# R&S®SMA100B RF AND MICROWAVE SIGNAL GENERATOR

**Specifications** 



Specifications
Version 08.00

ROHDE&SCHWARZ

Make ideas real



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## **Key features**

#### First class devices thanks to first class signals

- · Purest signals
  - Excellent SSB phase noise in base unit: < -120 dBc (typ.) for 10 GHz at an offset of 20 kHz
  - Outstanding SSB phase noise with option: < -132 dBc (typ.) for 10 GHz at an offset of 10 kHz
  - Lowest close-in SSB phase noise: < -83 dBc (typ.); f = 10 GHz, offset = 10 Hz
  - Virtually no wideband noise: < -162 dBc (typ.) at 10 GHz and an offset of 30 MHz
- Lowest harmonic and nonharmonic signal components
  - Very low harmonic signal components over the entire frequency range even at very high output power
  - Very low nonharmonic signal components of < -90 dBc (typ.) at 10 GHz

#### Very high output power without compromise

- · Exceptionally high output level
  - Ultra high output power up to 38 dBm with the 6 GHz model
  - Over 30 dBm at 18 GHz and 28 dBm at 20 GHz with the 20 GHz model
  - More than 30 dBm from 20 GHz to 35 GHz with the 40 GHz model
  - More than 19 dBm up to 70 GHz with the 67 GHz model
- · Excellent level accuracy and repeatability for CW signals, narrow pulses and modulated signals

#### User friendly in every detail

- Flexible 2 HU or 3 HU housing
- 3 HU with larger 7" display and multiple front panel connectors
- · Ergonomic operation thanks to state-of-the-art GUI with touch display

#### R&S®LegacyPro: refresh your technology

- Plug and play the R&S®SMA100B in an automated test system without changing the test software
- Emulation of R&S®SMA100A, R&S®SMF100A, Keysight PSG, Keysight MXG, etc.

### **Definitions**

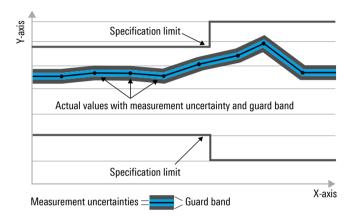
#### General

Product data applies under the following conditions:

- Three hours of storage at ambient temperature followed by 30 minutes of warm-up operation
- Specified environmental conditions met
- Recommended calibration interval adhered to
- All internal automatic adjustments performed, if applicable

#### Specifications with limits

Represent warranted product performance by means of a range of values for the specified parameter. These specifications are marked with limiting symbols such as  $\langle , , \rangle$ ,  $\geq$ ,  $\pm$ , or descriptions such as maximum, limit of, minimum. Compliance is ensured by testing or is derived from the design. Test limits are narrowed by guard bands to take into account measurement uncertainties, drift and aging, if applicable.



#### Specifications without limits

Represent warranted product performance for the specified parameter. These specifications are not specially marked and represent values with no or negligible deviations from the given value (e.g. dimensions or resolution of a setting parameter). Compliance is ensured by design.

#### Typical data (typ.)

Characterizes product performance by means of representative information for the given parameter. When marked with <, > or as a range, it represents the performance met by approximately 80 % of the instruments at production time. Otherwise, it represents the mean value.

#### Nominal values (nom.)

Characterize product performance by means of a representative value for the given parameter (e.g. nominal impedance). In contrast to typical data, a statistical evaluation does not take place and the parameter is not tested during production.

#### Measured values (meas.)

Characterize expected product performance by means of measurement results gained from individual samples.

#### Uncertainties

Represent limits of measurement uncertainty for a given measurand. Uncertainty is defined with a coverage factor of 2 and has been calculated in line with the rules of the Guide to the Expression of Uncertainty in Measurement (GUM), taking into account environmental conditions, aging, wear and tear.

Device settings and GUI parameters are indicated as follows: "parameter: value".

Typical data as well as nominal and measured values are not warranted by Rohde & Schwarz.

### Introduction

## Frequency options and step attenuator technology

Prerequisite is to install one of the following frequency options.

	Overview of installed step attenuator modules		
Frequency option	Electronic step attenuator up to 20 GHz	Mechanical step attenuator for complete frequency range	
R&S®SMAB-B103/-B106/-B112/-B120	•	_	
R&S <sup>®</sup> SMAB-B131/-B140(N)/ -B150(N)/-B167(N)	-	•	
R&S®SMAB-B131/-B140(N) with R&S®SMAB-B35 option	•	•	
R&S®SMAB-B131/-B140(N) with R&S®SMAB-B36S option	•	-	
R&S®SMAB-B150(N) with R&S®SMAB-B37 option	•	•	
R&S®SMAB-B167(N) with R&S®SMAB-B39 option	•	•	

• = installed, - = not available

If both, electronic and mechanical step attenuators are installed, the electronic step attenuator is used up to 20 GHz as default setting.

If the R&S®SMAB-B36S super ultra high output power option is installed, the electronic step attenuator is used up to 20 GHz. Above 20 GHz the mechanical step attenuator is used.

## Platform height options and hardware configurations

Depending on the hardware configuration the R&S®SMA100B is available with:

- 2 height units (2 HU; R&S®SMAB-B92 option) or
- 3 height units (3 HU; R&S®SMAB-B93 option).

The height unit option is together with the frequency option a prerequisite.

Frequency option	No high output power	With high output	With ultra high output	With super ultra high
	option installed	power option	power option	output power option
R&S®SMAB-B103	2 or 3 HU	2 or 3 HU	2 or 3 HU	_
R&S®SMAB-B106	2 or 3 HU	2 or 3 HU	2 or 3 HU	_
R&S®SMAB-B112	2 or 3 HU	2 or 3 HU	2 or 3 HU	_
R&S®SMAB-B120	2 or 3 HU	2 or 3 HU	2 or 3 HU	_
R&S®SMAB-B131	2 or 3 HU	3 HU	3 HU	3 HU
R&S®SMAB-B140,	2 or 3 HU	3 HU	3 HU	3 HU
R&S®SMAB-B140N				
R&S <sup>®</sup> SMAB-B150,	2 or 3 HU	3 HU	3 HU	_
R&S®SMAB-B150N				
R&S®SMAB-B167,	2 or 3 HU	3 HU	3 HU	_
R&S®SMAB-B167N				

## Frequency, high output power and rear panel connector options

The table shows the frequency options and their corresponding high output power, ultra high output power and rear panel connector options.

Frequency option	Super ultra high output power option			Rear panel connector option	
	Ultra high output po	ower option			
	High output power option				
R&S®SMAB-B103	R&S®SMAB-K31	R&S®SMAB-B32	_	R&S®SMAB-B80	
R&S®SMAB-B106	R&S®SMAB-K31	R&S®SMAB-B32	_	R&S®SMAB-B80	
R&S®SMAB-B112	R&S®SMAB-K33	R&S®SMAB-B34	_	R&S®SMAB-B81	
R&S®SMAB-B120	R&S®SMAB-K33	R&S®SMAB-B34	_	R&S®SMAB-B81	
R&S®SMAB-B131	R&S®SMAB-B35	R&S®SMAB-K36	R&S®SMAB-B36S	R&S®SMAB-B81	
R&S®SMAB-B140, R&S®SMAB-B140N	R&S®SMAB-B35	R&S®SMAB-K36	R&S®SMAB-B36S	R&S®SMAB-B81	
R&S®SMAB-B150,	R&S®SMAB-B37	R&S®SMAB-K38	_	R&S®SMAB-B82	
R&S®SMAB-B150N					
R&S®SMAB-B167,	R&S®SMAB-B39	R&S®SMAB-K40	_	R&S®SMAB-B82	
R&S®SMAB-B167N					

#### Notes:

- An ultra high output power option requires the corresponding high output power option to be installed.
   For example, R&S®SMAB-K31 is a prerequisite for R&S®SMAB-B32.
- R&S®SMAB-B36S super ultra high output power option requires R&S®SMAB-K36 ultra high output power option and R&S®SMAB-B35 high output power option.

## **RF** characteristics

Unless stated otherwise, the specifications apply within the specified level range.

## **Frequency**

Range	R&S®SMAB-B103	8 kHz to 3 GHz	
	R&S®SMAB-B106	8 kHz to 6 GHz	
	R&S®SMAB-B112	8 kHz to 12.75 GHz	
	R&S®SMAB-B120	8 kHz to 20 GHz	
	R&S®SMAB-B131	8 kHz to 31.8 GHz	
	R&S®SMAB-B140/-B140N	8 kHz to 40 GHz	
	R&S®SMAB-B150/-B150N	8 kHz to 50 GHz	
	R&S®SMAB-B167/-B167N	8 kHz to 67 GHz	
	overrange	67 GHz to 72 GHz	
Resolution of setting		0.001 Hz	
Resolution of synthesis	f = 1 GHz	0.053 nHz (nom.)	
Setting time	CW, to within $< 1 \times 10^{-7}$ for f $> 10$ MHz or $<$	30 Hz for f < 10 MHz, with GUI update	
	stopped, after IEC/IEEE bus delimiter (with	out LAN connection), with R&S®SMAB-B86	
	option, level setting characteristic: auto		
	with R&S®SMAB-B103/-B106/-B112/	< 2.0 ms	
	-B120 option		
	with R&S®SMAB-B131/-B140(N)/	< 2.5 ms	
	-B150(N)/-B167(N) option		
	with R&S®SMAB-B711(N) option	< 5.5 ms	
Resolution of phase offset setting		adjustable in 0.01° steps	
Maximum phase-continuous frequency	synthesizer remains in phase locked state	0.02 % of set frequency (nom.)	
step <sup>1</sup>	during frequency step		
Phase-continuous frequency setting		≥ 1.64 % of set frequency	
range 1	instruments equipped with R&S®SMAB-B71	11(N) ultra low phase noise option	
	narrow mode	≥ 0.163 % of set frequency	
	wide mode	≥ 1.47 % of set frequency	

## Reference frequency

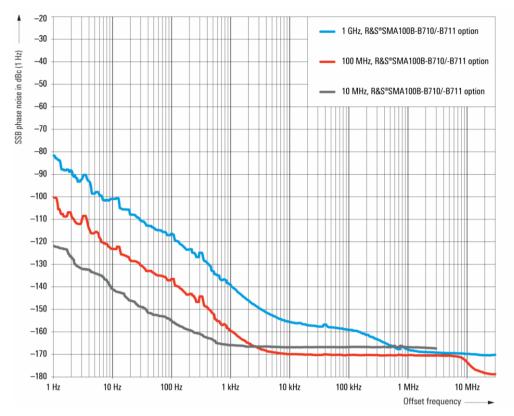
Frequency error	at time of calibration in production	
	standard or with R&S®SMAB-B1H/	< 1 x 10 <sup>-8</sup>
	-B709 option	
	with R&S®SMAB-B710(N)/-B711(N)	< 5 × 10 <sup>-9</sup>
	option	
Aging	after 30 days of uninterrupted operation	
	standard	≤ 1 × 10 <sup>-9</sup> /day,
		≤ 1 × 10 <sup>-7</sup> /year
	with R&S®SMAB-B1H/-B709/-B710(N)/	$\leq 5 \times 10^{-10}/\text{day}$
	-B711(N) option	≤ 3 × 10 <sup>-8</sup> /year
Temperature effect	in temperature range from 0 °C to +55 °C	
	standard	±6 x 10 <sup>-8</sup>
	with R&S®SMAB-B1H/-B709 option	±6 x 10 <sup>-9</sup>
	with R&S®SMAB-B710(N)/-B711(N)	±3 x 10 <sup>-9</sup>
	option	
Warm-up time	to nominal thermostat temperature	≤ 10 min (nom.)

<sup>&</sup>lt;sup>1</sup> Spectral purity not tested in this mode.

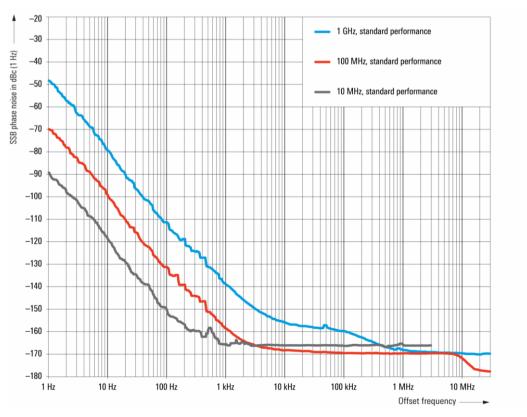
Input for external reference frequence Connector type	REF in on rear panel	BNC female	
Input frequency	standard	10 MHz	
mpat noquonoy	with R&S®SMAB-K703 option	10 MHz, 100 MHz	
	with R&S®SMAB-K704 option	10 MHz,	
	with read divined revolution	1 MHz to 100 MHz, variable	
Input frequency setting resolution	with R&S®SMAB-K704 option	0.1 Hz	
Input level range	level limits	0 dBm to 20 dBm	
input level range	recommended input level for optimum	7 dBm to 13 dBm	
	phase noise performance	7 dBill to 10 dBill	
Input impedance	prided rioles performance	50 Ω (nom.)	
Minimum frequency locking range	synchronization bandwidth: wide	±3 × 10 <sup>-6</sup>	
will in requerity looking range	synchronization bandwidth: narrow		
	standard or with R&S®SMAB-B1H/	±0.3 × 10 <sup>-6</sup>	
	-B709 option	10.3 × 10	
	with R&S®SMAB-B710(N)/-B711(N)	±0.15 × 10 <sup>-6</sup>	
	option		
Output for internal reference frequen	•	·	
Connector type	REF out on rear panel	BNC female	
Output frequency	standard	sine wave, 10 MHz	
	with R&S®SMAB-K703 option	sine wave, 10 MHz, 100 MHz	
	with R&S®SMAB-K704 option	,	
	instrument set to internal reference	sine wave, 10 MHz	
	instrument set to external reference	sine wave, 10 MHz,	
	monamon ser te extense recense	applied external reference frequency	
Output level		7 dBm to 14 dBm	
Source impedance		50 Ω (nom.)	
Wideband noise	with R&S®SMAB-K703 option,	< -163 dBc, -167 dBc (typ.)	
Waddana noloo	100 MHz, internal reference,	100 420, 107 420 (1)p.)	
	carrier offset = 10 MHz,		
	measurement bandwidth: 1 Hz		
Ultra low noise 1 GHz reference frequ			
Input connector type	1 GHz in on rear panel	SMA female	
Input frequency	1 Of 12 III of 1 foot partor	1 GHz	
Input level range	level limits	≥ 6 dBm, ≤ 20 dBm	
mpat lover range	recommended input level for optimum	7 dBm to 13 dBm	
	phase noise performance	, abilito 10 abili	
Input impedance	phase holde politimanide	50 Ω (nom.)	
Minimum frequency locking range		±3 × 10 <sup>-6</sup>	
Output connector type	1 GHz out on rear panel	SMA female	
Output connector type  Output frequency	1 Of 12 out of Total pariet	sine wave 1 GHz	
Output frequency Output level		7 dBm to 13 dBm	
Source impedance		7 dBill to 13 dBill 50 Ω (nom.)	
	1 GHz internal reference	< –164 dBc, –168 dBc (typ.)	
Wideband noise	1 GHz, internal reference, carrier offset = 10 MHz,	< -104 abc, -100 abc (typ.)	
	measurement bandwidth: 1 Hz		
Input for electronic tuning of internal			
	·	PNC famala	
Connector type	external tune on rear panel	BNC female	
Sensitivity	external tuning slope, low	$1.1 \times 10^{-8}$ (typ.)	
	external tuning slope, high	6 × 10 <sup>-8</sup> /V (typ.)	
Input voltage range		-10 V to +10 V	
Input impedance		10 kΩ (nom.)	

## Overview of synchronization bandwidth of reference PLL with external reference frequency

External reference frequency	Synchronization bandwidth (nominal)		
	Bandwidth set to narrow	Bandwidth set to wide	
10 MHz	0.5 Hz	100 Hz	
100 MHz (with R&S®SMAB-K703 option)	0.5 Hz	250 Hz	
Flexible reference input frequency from	0.5 Hz	5 Hz	
1 MHz to 100 MHz			
(with R&S®SMAB-K704 option)			
1 GHz (with R&S®SMAB-K703 option)	5 Hz	> 150 kHz	



Measured SSB phase noise of reference outputs at f = 10 MHz, 100 MHz and 1 GHz with the R&S®SMAB-B710(N) and R&S®SMAB-B711(N) options (f = 100 MHz and 1 GHz only available with the R&S®SMAB-K703 option)



Measured SSB phase noise of reference outputs at f = 10 MHz, 100 MHz and 1 GHz (f = 100 MHz and f = 1 GHz are only available with the R&S®SMAB-K703 option)

#### Reference frequency option concept

		Without option	With R&S®SMAB-K703 option, 1 GHz reference	With R&S®SMAB-K704 option, variable reference input
	10 MHz input frequency	•	•	•
<b>_</b>	100 MHz input frequency	_	•	•
INPUT	1 MHz to 100 MHz input	_	_	•
Z	frequency			
	1 GHz input frequency	_	•	_
	10 MHz output frequency	•	•	•
5	100 MHz output frequency	_	•	_
⊢₽	"Loop through" of input to	_	•	•
OUTP	output			
	1 GHz output frequency	_	•	_

#### R&S®SMAB-K703 option (1 GHz reference)

When this option is installed, the user can use the 1 GHz low noise input and output for synchronization.

In WIDE mode, the signal generator will use this signal directly as a reference for the synthesizer.

This option should be used if a very high phase stability between multiple generators is required.

The 100 MHz low noise input and output mode is only available with this option.

#### R&S®SMAB-K704 option (variable reference input)

When this option is installed, the user can set the reference input frequency in 0.1 Hz steps between 1.0 MHz and 100 MHz.

The signal generator will lock its internal reference oscillator on the input frequency.

The reference output frequency can be set independently from the input frequency.

#### Note on choosing the proper reference synchronization bandwidth

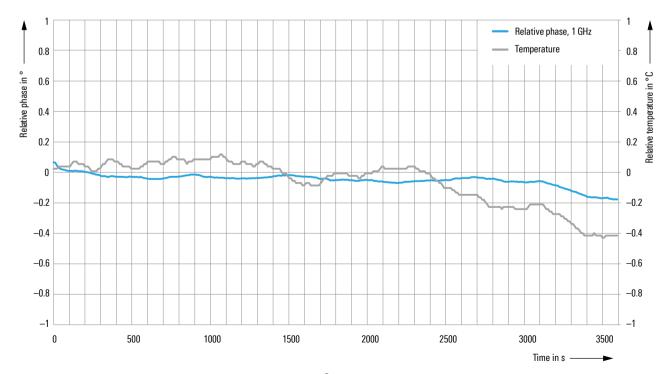
The user has the choice to set the synchronization bandwidth either to NARROW or WIDE.

In WIDE mode, the best possible phase stability is achieved.

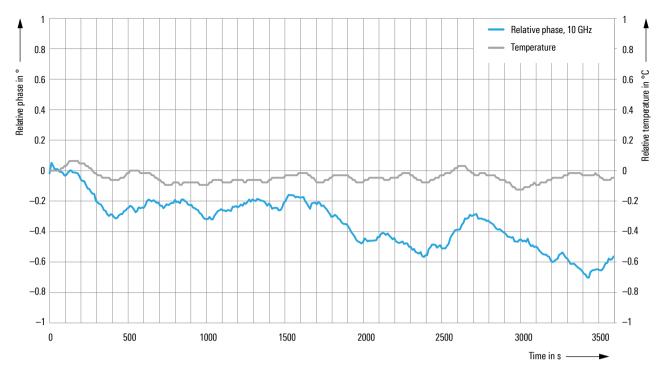
The phase noise performance close to the carrier depends on the phase noise of the external signal source.

In NARROW mode, the reference PLL acts as a clean-up-loop in which the phase noise is mainly determined by the signal generator's internal reference source. This mode is recommended when using external reference sources with close-to-carrier phase noise worse than the R&S®SMA100B (i. e. rubidium standards).

Please note that due to the slow synchronization, reference locking can take up to 10 seconds.



Measured relative phase versus time of two R&S $^{\circ}$ SMA100B instruments at f = 1 GHz carrier frequency, coupled with 1 GHz reference frequency (R&S $^{\circ}$ SMAB-K703 option)



Measured relative phase versus time of two R&S $^{\circ}$ SMA100B instruments at f = 10 GHz carrier frequency, coupled with 1 GHz reference frequency (R&S $^{\circ}$ SMAB-K703 option)



Measured relative phase versus time of two R&S $^{\circ}$ SMA100B instruments at f = 56 GHz carrier frequency, coupled with 1 GHz reference frequency (R&S $^{\circ}$ SMAB-K703 option)

## Level

Specified level range	peak envelope power (PEP)		
R&S®SMAB-B103/-B106	standard		
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm	
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm	
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm	
	1 MHz < f ≤ 6 GHz	-127 dBm to +19 dBm	
	with R&S®SMAB-K31 option		
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm	
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm	
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm	
	1 MHz < f ≤ 6 GHz	-127 dBm to +25 dBm	
	with R&S®SMAB-K31/-B32 option		
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm	
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm	
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm	
	1 MHz < f ≤ 8 MHz	-127 dBm to +25 dBm	
	8 MHz < f ≤ 6 GHz	-127 dBm to +30 dBm	
R&S®SMAB-B112/-B120	standard	TET GETTIC TOO GETTI	
011110 01121 0120	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm	
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm	
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm	
	1 MHz < f ≤ 6 GHz	-127 dBm to +18 dBm	
	6 GHz < f ≤ 13 GHz	-120 dBm to +18 dBm	
	13 GHz < f ≤ 20 GHz	-120 dBm to +17 dBm	
	with R&S®SMAB-K33 option		
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm	
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm	
	100 kHz < f ≤ 1 MHz	-90 dBm to +13 dBm	
	1 MHz < f ≤ 6 GHz	-127 dBiff to +13 dBiff	
	6 GHz < f ≤ 20 GHz	-127 dBm to +23 dBm -120 dBm to +20 dBm <sup>2</sup>	
	with R&S®SMAB-K33/-B34 option	-120 dBill to +20 dBill	
		00 dDm to 10 dDm	
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm	
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm	
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm	
	1 MHz < f ≤ 8 MHz	-127 dBm to +25 dBm	
	8 MHz < f ≤ 6 GHz	-127 dBm to +28 dBm	
	6 GHz < f ≤ 18 GHz	-120 dBm to +27 dBm <sup>2</sup>	
DOOROMAD DAGA DAGA DAGA	18 GHz < f ≤ 20 GHz	-120 dBm to +24 dBm <sup>2</sup>	
R&S <sup>®</sup> SMAB-B131/-B140/-B140N	standard	00 dDm to 0 dD	
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm	
	20 kHz < f ≤ 100 kHz	–90 dBm to +13 dBm	
	100 kHz < f ≤ 1 MHz	-120 dBm to +13 dBm	
	1 MHz < f ≤ 18 GHz	-120 dBm to +14 dBm	
	18 GHz < f ≤ 40 GHz	-120 dBm to +13 dBm	
	with R&S®SMAB-B35 option		
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm	
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm	
	100 kHz < f ≤ 1 MHz	–127 dBm to +13 dBm	
	1 MHz < f ≤ 3 GHz	-127 dBm to +22 dBm	
	3 GHz < f ≤ 6 GHz	-127 dBm to +18 dBm	
	6 GHz < f ≤ 18 GHz	-120 dBm to +18 dBm <sup>2</sup>	
	18 GHz < f ≤ 37 GHz	-120 dBm to +17 dBm <sup>2</sup>	
	37 GHz < f ≤ 40 GHz	-120 dBm to +16 dBm <sup>2</sup>	

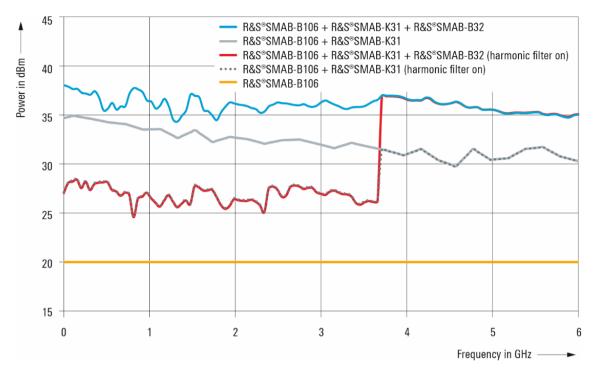
<sup>2</sup> With the R&S®SMAB-B81/-B82 rear panel connectors option, for f > 6 GHz the level is reduced by (0.2 dB + 0.025 dB/GHz).

R&S®SMAB-B131/-B140/-B140N	with R&S®SMAB-B35/-K36 options			
(continued)	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm		
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm		
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm		
	1 MHz < f ≤ 3 GHz	-127 dBm to +24 dBm		
	3 GHz < f ≤ 6 GHz	-127 dBm to +21 dBm <sup>2</sup>		
	6 GHz < f ≤ 18 GHz	-120 dBm to +21 dBm <sup>2</sup>		
	18 GHz < f ≤ 20 GHz	-120 dBm to +20 dBm <sup>2</sup>		
	20 GHz < f ≤ 33 GHz	-120 dBm to +22 dBm <sup>2</sup>		
	33 GHz < f ≤ 37 GHz	-120 dBm to +20 dBm <sup>2</sup>		
	37 GHz < f ≤ 40 GHz	-120 dBm to +19 dBm <sup>2</sup>		
	with R&S®SMAB-B35/-K36/-B36S options			
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm		
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm		
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm		
	1 MHz < f ≤ 8 MHz	-127 dBm to +24 dBm		
	8 MHz < f ≤ 3 GHz	-127 dBm to +29 dBm		
	3 GHz < f ≤ 6 GHz	-127 dBm to +28 dBm		
	6 GHz < f ≤ 18 GHz	-120 dBm to +24 dBm <sup>2</sup>		
	18 GHz < f ≤ 20 GHz	-120 dBm to +22 dBm <sup>2</sup>		
	20 GHz < f ≤ 33 GHz	-120 dBm to +27 dBm <sup>2</sup>		
	33 GHz < f ≤ 38 GHz	-120 dBm to +26 dBm <sup>2</sup>		
	38 GHz < f ≤ 40 GHz	-120 dBm to +25 dBm <sup>2</sup>		
R&S®SMAB-B150/-B150N/	instruments with serial number < 120			
-B167/-B167N	standard			
	8 kHz < f ≤ 100 kHz	-90 dBm to +8 dBm		
	100 kHz < f ≤ 20 GHz	-95 dBm to +8 dBm		
	20 GHz < f ≤ 40 GHz	-95 dBm to +5 dBm		
	40 GHz < f ≤ 67 GHz	-75 dBm to +5 dBm		
	with R&S®SMAB-B37/-B39 option			
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm		
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm		
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm		
	1 MHz < f ≤ 3 GHz	-127 dBm to +21 dBm		
	3 GHz < f ≤ 6 GHz	-127 dBm to +18 dBm		
	6 GHz < f ≤ 18 GHz	-120 dBm to +18 dBm <sup>2</sup>		
	18 GHz < f ≤ 20 GHz	-120 dBm to +15 dBm <sup>2</sup>		
	20 GHz < f ≤ 33 GHz	-95 dBm to +15 dBm <sup>2</sup>		
	33 GHz < f ≤ 40 GHz	-95 dBm to +11 dBm <sup>2</sup>		
	40 GHz < f ≤ 65 GHz	-75 dBm to +11 dBm <sup>2</sup>		
	65 GHz < f ≤ 67 GHz	-75 dBm to +9 dBm <sup>2</sup>		
	with R&S®SMAB-B37/-K38/-B39/			
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm		
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm		
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm		
	1 MHz < f ≤ 3 GHz			
	3 GHz < f ≤ 6 GHz	-127 dBm to +23 dBm		
		-127 dBm to +20 dBm		
	6 GHz < f ≤ 18 GHz	-120 dBm to +20 dBm <sup>2</sup>		
	18 GHz < f ≤ 20 GHz	-120 dBm to +17 dBm <sup>2</sup>		
	20 GHz < f ≤ 33 GHz	-95 dBm to +18 dBm <sup>2</sup>		
	33 GHz < f ≤ 40 GHz	-95 dBm to +15 dBm <sup>2</sup>		
	40 GHz < f ≤ 52 GHz	-95 dBm to +18 dBm <sup>2</sup>		
	52 GHz < f ≤ 65 GHz	-75 dBm to +15 dBm <sup>2</sup>		
	65 GHz < f ≤ 67 GHz	-75 dBm to +10 dBm <sup>2</sup>		

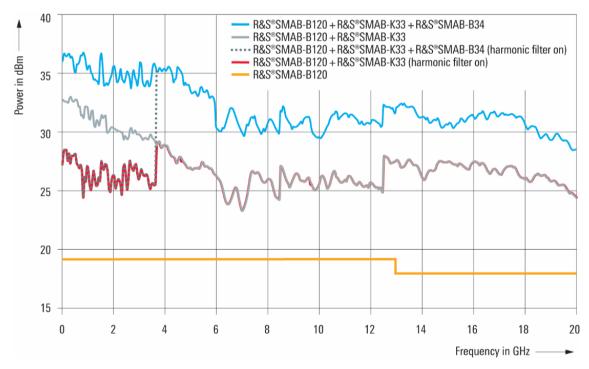
	instruments with serial number ≥ 120	000
	standard	
	8 kHz < f ≤ 100 kHz	-90 dBm to +8 dBm
	100 kHz < f ≤ 20 GHz	-95 dBm to +8 dBm
	20 GHz < f ≤ 40 GHz	-95 dBm to +5 dBm
	40 GHz < f ≤ 67 GHz	-75 dBm to +5 dBm
	with R&S®SMAB-B37/-B39 option	
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm
	1 MHz < f ≤ 3 GHz	-127 dBm to +21 dBm
	3 GHz < f ≤ 6 GHz	-127 dBm to +18 dBm
	6 GHz < f ≤ 18 GHz	-120 dBm to +18 dBm <sup>2</sup>
	18 GHz < f ≤ 33 GHz	-120 dBm to +15 dBm <sup>2</sup>
	33 GHz < f ≤ 40 GHz	-120 dBm to +11 dBm <sup>2</sup>
	40 GHz < f ≤ 65 GHz	-115 dBm to +11 dBm <sup>2</sup>
	65 GHz < f ≤ 67 GHz	-115 dBm to +9 dBm <sup>2</sup>
	with R&S®SMAB-B37/-K38/-B39/-	
	8 kHz < f ≤ 20 kHz	-90 dBm to +8 dBm
	20 kHz < f ≤ 100 kHz	-90 dBm to +13 dBm
	100 kHz < f ≤ 1 MHz	-127 dBm to +13 dBm
	1 MHz < f ≤ 3 GHz	-127 dBm to +23 dBm
	3 GHz < f ≤ 6 GHz	-127 dBm to +20 dBm
	6 GHz < f ≤ 18 GHz	-120 dBm to +20 dBm <sup>2</sup>
	18 GHz < f ≤ 20 GHz	-120 dBm to +17 dBm <sup>2</sup>
	20 GHz < f ≤ 33 GHz	-120 dBm to +17 dBm <sup>2</sup>
	33 GHz < f ≤ 40 GHz	-120 dBm to +15 dBm <sup>2</sup>
	40 GHz < f ≤ 52 GHz	-120 dBin to +13 dBin 2
	52 GHz < f ≤ 65 GHz	-115 dBm to +17 dBm <sup>2</sup>
	65 GHz < f ≤ 67 GHz	-115 dBm to +17 dBm <sup>2</sup>
Setting range	00 0112 -1 = 01 0112	110 dbill to 110 dbill
R&S®SMAB-B103/-B106	standard	-145 dBm to +20 dBm
	with R&S®SMAB-K31 option	1 10 dbiii to 120 dbiii
	f ≤ 1 MHz	-145 dBm to +30 dBm
	f > 1 MHz	-145 dBm to +35 dBm
	with R&S®SMAB-B32 option	140 dom to 100 dom
	f ≤ 1 MHz	-145 dBm to +30 dBm
	f > 1 MHz	-145 dBm to +40 dBm
R&S®SMAB-B112/-B120	standard	
	f ≤ 13 GHz	-145 dBm to +19 dBm
	f > 13 GHz	-145 dBm to +18 dBm
	with R&S®SMAB-K33 option	1 to dom to 1 to dom
	f ≤ 1 MHz	-145 dBm to +30 dBm
	f > 1 MHz	-145 dBm to +35 dBm
	with R&S®SMAB-B34 option	140 dom to 100 dom
	f ≤ 1 MHz	-145 dBm to +30 dBm
	f > 1 MHz	-145 dBm to +40 dBm
R&S®SMAB-B131/-B140/-B140N	standard	170 dom to 170 dom
100 OMAD D101/-D140/-D140N	f ≤ 18 GHz	-145 dBm to +16 dBm
	f > 18 GHz	-145 dBm to +15 dBm
	with R&S®SMAB-B35/-K36/-B36S op	
	f ≤ 1 MHz	-145 dBm to +30 dBm
	f > 1 MHz	-145 dBm to +40 dBm
R&S <sup>®</sup> SMAB-B150/-B167/	standard	-140 UDIII (U T40 UDIII
-B150N/-B167N	f ≤ 20 GHz	-145 dBm to +10 dBm
DIOUN DIOIN	f > 20 GHz	-145 dBm to +7 dBm
	with R&S®SMAB-B37/-B39 option	-140 UDIII (U T7 UDIII
	f ≤ 1 MHz	-145 dBm to +30 dBm
	f > 1 MHz	-145 dBm to +30 dBm
	with R&S®SMAB-B150/-B167/-K38/-k	
	f ≤ 1 MHz	-145 dBm to +30 dBm
	f > 1 MHz	-145 dBm to +35 dBm
	with R&S <sup>®</sup> SMAB-B150N/-B167N/-K3	
	f ≤ 1 MHz	–145 dBm to +30 dBm
	1 ≤ 1 MHz 1 MHz < f ≤ 40 GHz	-145 dBm to +35 dBm
	f > 40 GHz	-145 dBm to +35 dBm -145 dBm to +19 dBm
	1 2 40 GHZ	-140 UDIII (U +19 UDIII

### Version 08.00, February 2024

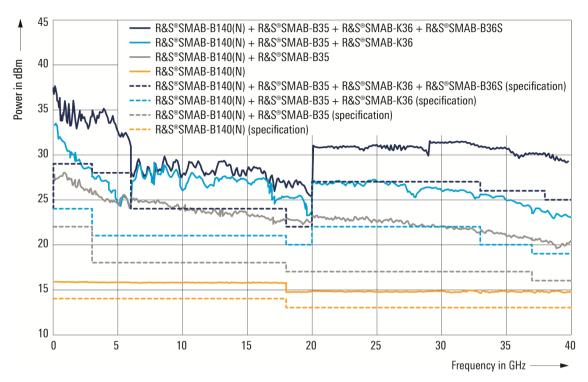
Setting resolution		0.01 dB				
Level accuracy	CW, level setting characteristic: auto, temperature range from +18 °C to +33 °C					
	level from -90 dBm to +25 dBm	level from -90 dBm to +25 dBm				
	8 kHz < f ≤ 8 MHz	< 1.0 dB				
	8 MHz < f ≤ 3 GHz	< 0.5 dB				
	3 GHz < f ≤ 20 GHz	< 0.9 dB				
	20 GHz < f ≤ 40 GHz	< 1.0 dB				
	40 GHz < f ≤ 50 GHz	< 1.5 dB				
	50 GHz < f ≤ 67 GHz	< 2.0 dB				
	level > +25 dBm	level > +25 dBm				
	8 MHz < f ≤ 18 GHz	< 1.0 dB				
	level < -90 dBm					
	100 kHz < f ≤ 8 MHz	< 1.2 dB				
	8 MHz < f ≤ 3 GHz	< 0.8 dB				
	3 GHz < f ≤ 20 GHz	< 1.2 dB				
	20 GHz < f ≤ 40 GHz	< 1.5 dB				
	40 GHz < f ≤ 50 GHz	< 2.0 dB				
	50 GHz < f ≤ 67 GHz	< 2.5 dB				
Interruption-free level setting range	level setting characteristic:	> 20 dB				
menuphon nee lever setting range	uninterrupted level setting	2 20 UB				
	with R&S®SMAB-K724 option,					
	level setting characteristic: high dynamic uninterrupted					
	f > 52 MHz	> 60 dB, 70 dB (typ.)				
Additional level error	ALC state off (table)	< 0.7 dB				
Additional level effor		g characteristic: high dynamic uninterrupted,				
		, specifications are measured for f > 40 GHz				
	attenuation range					
	0 dB < m ≤ 10 dB	< 0.25 dB				
	10 dB < m ≤ 20 dB	< 1 dB				
	10 dB < m ≤ 20 dB 20 dB < m ≤ 40 dB	< 1 dB < 2 dB (typ.)				
	10 dB < m ≤ 20 dB 20 dB < m ≤ 40 dB 40 dB < m ≤ 50 dB	< 1 dB < 2 dB (typ.) < 3 dB (typ.)				
Softing time	10 dB < m ≤ 20 dB 20 dB < m ≤ 40 dB 40 dB < m ≤ 50 dB 50 dB < m ≤ 60 dB	< 1 dB < 2 dB (typ.) < 3 dB (typ.) < 4 dB (typ.)				
Setting time	10 dB < m $\le$ 20 dB 20 dB < m $\le$ 40 dB 40 dB < m $\le$ 50 dB 50 dB < m $\le$ 60 dB CW, level deviation < 0.1 dB from final va	< 1 dB < 2 dB (typ.) < 3 dB (typ.) < 4 dB (typ.) lue, with GUI update stopped, temperature				
Setting time	10 dB < m ≤ 20 dB 20 dB < m ≤ 40 dB 40 dB < m ≤ 50 dB 50 dB < m ≤ 60 dB CW, level deviation < 0.1 dB from final va range from +18 °C to +33 °C, after IEC/IE	< 1 dB < 2 dB (typ.) < 3 dB (typ.) < 4 dB (typ.) lue, with GUI update stopped, temperature EE bus delimiter (without LAN connection),				
Setting time	10 dB < m $\le$ 20 dB 20 dB < m $\le$ 40 dB 40 dB < m $\le$ 50 dB 50 dB < m $\le$ 60 dB CW, level deviation < 0.1 dB from final varange from +18 °C to +33 °C, after IEC/IE with R&S®SMAB-B86 option, level setting	< 1 dB < 2 dB (typ.) < 3 dB (typ.) < 4 dB (typ.) lue, with GUI update stopped, temperature EE bus delimiter (without LAN connection), characteristic: auto, no relay switchover				
Setting time	10 dB < m $\le$ 20 dB 20 dB < m $\le$ 40 dB 40 dB < m $\le$ 50 dB 50 dB < m $\le$ 60 dB CW, level deviation < 0.1 dB from final va range from +18 °C to +33 °C, after IEC/IE with R&S®SMAB-B86 option, level setting R&S®SMAB-B103/-B106/-B112/-B120	< 1 dB < 2 dB (typ.) < 3 dB (typ.) < 4 dB (typ.) lue, with GUI update stopped, temperature EE bus delimiter (without LAN connection), characteristic: auto, no relay switchover < 1.5 ms				
Setting time	10 dB < m $\le$ 20 dB 20 dB < m $\le$ 40 dB 40 dB < m $\le$ 50 dB 50 dB < m $\le$ 60 dB CW, level deviation < 0.1 dB from final varange from +18 °C to +33 °C, after IEC/IE with R&S®SMAB-B86 option, level setting	< 1 dB < 2 dB (typ.) < 3 dB (typ.) < 4 dB (typ.) lue, with GUI update stopped, temperature EE bus delimiter (without LAN connection), characteristic: auto, no relay switchover				
Setting time	10 dB < m $\le$ 20 dB 20 dB < m $\le$ 40 dB 40 dB < m $\le$ 50 dB 50 dB < m $\le$ 60 dB CW, level deviation < 0.1 dB from final varange from +18 °C to +33 °C, after IEC/IE with R&S®SMAB-B86 option, level setting R&S®SMAB-B103/-B106/-B112/-B120 R&S®SMAB-B131/-B140(N)/-B150(N)/	< 1 dB < 2 dB (typ.) < 3 dB (typ.) < 4 dB (typ.) lue, with GUI update stopped, temperature EE bus delimiter (without LAN connection), characteristic: auto, no relay switchover < 1.5 ms				
v	10 dB < m ≤ 20 dB 20 dB < m ≤ 40 dB 40 dB < m ≤ 50 dB 50 dB < m ≤ 60 dB  CW, level deviation < 0.1 dB from final va range from +18 °C to +33 °C, after IEC/IE with R&S®SMAB-B86 option, level setting R&S®SMAB-B103/-B106/-B112/-B120  R&S®SMAB-B131/-B140(N)/-B150(N)/-B167(N) with switching of mechanical step attenuator	< 1 dB < 2 dB (typ.) < 3 dB (typ.) < 4 dB (typ.) lue, with GUI update stopped, temperature EE bus delimiter (without LAN connection), characteristic: auto, no relay switchover < 1.5 ms < 1.7 ms				
Setting time  Level setting characteristics	10 dB < m ≤ 20 dB 20 dB < m ≤ 40 dB 40 dB < m ≤ 50 dB 50 dB < m ≤ 60 dB CW, level deviation < 0.1 dB from final varange from +18 °C to +33 °C, after IEC/IE with R&S $^{\circ}$ SMAB-B86 option, level setting R&S $^{\circ}$ SMAB-B103/-B106/-B112/-B120 R&S $^{\circ}$ SMAB-B131/-B140(N)/-B150(N)/-B167(N) with switching of mechanical step	< 1 dB < 2 dB (typ.) < 3 dB (typ.) < 4 dB (typ.) lue, with GUI update stopped, temperature EE bus delimiter (without LAN connection), characteristic: auto, no relay switchover < 1.5 ms < 1.7 ms < 25 ms				
v	10 dB < m ≤ 20 dB 20 dB < m ≤ 40 dB 40 dB < m ≤ 50 dB 50 dB < m ≤ 60 dB  CW, level deviation < 0.1 dB from final va range from +18 °C to +33 °C, after IEC/IE with R&S®SMAB-B86 option, level setting R&S®SMAB-B103/-B106/-B112/-B120  R&S®SMAB-B131/-B140(N)/-B150(N)/-B167(N)  with switching of mechanical step attenuator  predefined modes to optimize the instrument behavior for common	< 1 dB < 2 dB (typ.) < 3 dB (typ.) < 4 dB (typ.) lue, with GUI update stopped, temperature EE bus delimiter (without LAN connection), characteristic: auto, no relay switchover < 1.5 ms < 1.7 ms < 25 ms  • auto • uninterrupted level setting				
v	10 dB < m ≤ 20 dB 20 dB < m ≤ 40 dB 40 dB < m ≤ 50 dB 50 dB < m ≤ 60 dB  CW, level deviation < 0.1 dB from final va range from +18 °C to +33 °C, after IEC/IE with R&S®SMAB-B86 option, level setting R&S®SMAB-B103/-B106/-B112/-B120  R&S®SMAB-B131/-B140(N)/-B150(N)/-B167(N) with switching of mechanical step attenuator predefined modes to optimize the	< 1 dB < 2 dB (typ.) < 3 dB (typ.) < 4 dB (typ.) lue, with GUI update stopped, temperature EE bus delimiter (without LAN connection), characteristic: auto, no relay switchover < 1.5 ms < 1.7 ms < 25 ms  • auto • uninterrupted level setting				



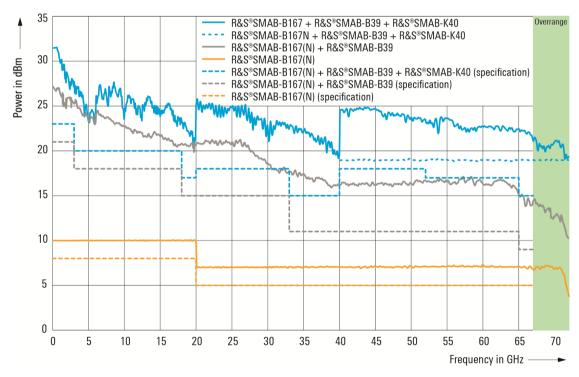
Measured maximum available output power versus frequency



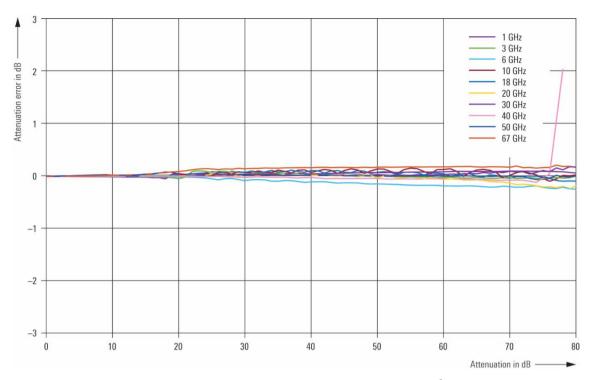
Measured maximum available output power versus frequency



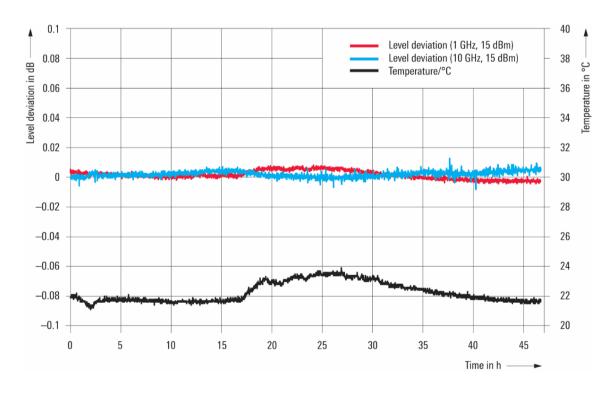
Specified and measured maximum available output power versus frequency



Specified and measured maximum available output power versus frequency



Measured level linearity of high dynamic uninterrupted level sweep with the R&S®SMAB-K724 option



Measured level repeatability and ambient temperature over 46 h. The figure shows the very high level repeatability at 15 dBm output level for 1 GHz and 10 GHz carrier frequency. During two consecutive measurements, the output level was set to different random level values

## **Reverse power**

Reverse power (from 50 Ω source)	maximum permissible reverse RF power with R&S®SMAB-B103/-B106;			
	in case of too high reverse power, the RF of	in case of too high reverse power, the RF output is switched off by a mechanical relay		
	1 MHz < f ≤ 3 GHz	50 W		
	3 GHz < f < 6 GHz	10 W		
	maximum permissible reverse RF power with R&S®SMAB-B112/-B120/-B131/-B140/			
	-B140N/-B150/-B150N/-B167/-B167N			
	1 MHz < f ≤ 67 GHz	0.5 W		
Maximum permissible DC voltage	R&S®SMAB-B103/-B106	50 V		
	R&S <sup>®</sup> SMAB-B112/-B120	5 V		
	R&S®SMAB-B131/-B140/-B140N/-B150/	1 V		
	-B150N/-B167/-B167N			

## **VSWR**

Output impedance VSWR in 50 Ω system,	R&S <sup>®</sup> SMAB-B103/-B106		
ALC state auto	200 kHz < f ≤ 6 GHz	< 1.6	
	R&S®SMAB-B112/-B120		
	200 kHz < f ≤ 3 GHz	< 1.9 (meas.)	
	3 GHz < f ≤ 6 GHz	< 1.7 (meas.)	
	6 GHz < f ≤ 20 GHz	< 1.6 (meas.)	
	R&S®SMAB-B112/-B120 with R&S®SMAB-B34		
	200 kHz < f ≤ 3 GHz	< 1.9 (meas.)	
	3 GHz < f ≤ 6 GHz	< 1.7 (meas.)	
	6 GHz < f ≤ 20 GHz	< 1.8 (meas.)	
	R&S®SMAB-B131/-B140/-B140N/-B150/-B1	150N/-B167/-B167N	
	200 kHz < f ≤ 3 GHz	< 1.9 (meas.)	
	3 GHz < f ≤ 50 GHz	< 2.0 (meas.)	

## Frequency and level sweep

Operating mode		digital sweep in discrete steps	
Sweep parameters		RF frequency,	
		RF level,	
		RF frequency and RF level	
Trigger modes	execute sweep continuously with internal	auto	
	trigger source		
	execute one full sweep	single	
	execute one step	step	
	sweep start and stop controlled by external trigger signal	start/stop	
Trigger source	55 5	external trigger signal (INST TRIG	
		at rear), rotary knob, touch panel,	
		remote fcontrol	
Sweep range		full specified frequency and level range	
	interruption-free level sweep with	0.01 dB to 20 dB	
	attenuator mode fixed		
	high dynamic uninterrupted level sweep with R&S®SMAB-K724 option		
	f > 52 MHz	0.01 dB to 60 dB, 70 dB (typ.)	
Sweep shape		sawtooth, triangle	
Step size setting resolution	frequency sweep linear	0.001 Hz	
	frequency sweep logarithmic	0.01 %	
	level sweep	0.01 dB	
Dwell time setting range	RF level sweep	3 ms to 100 s	
_	RF frequency sweep	3 ms to 100 s	
	with R&S®SMAB-B711(N) option	5 ms to 100 s	
Dwell time setting resolution		0.1 ms	

## Ramp sweep (R&S®SMAB-B28 option)

Operating mode		synthesized frequency sweep (up direction)
Trigger modes	execute sweep continuously	auto
	execute one full sweep	single
Trigger source		external trigger signal (INST TRIG
		at rear), rotary knob, touchpanel,
		remote control
Sweep span range	with R&S®SMAB-B103/-B106/-B112/	full frequency range
	-B120/-B131/-B140(N)/-B150/-B167	
	options	
	with R&S®SMAB-B150N/-B167N options	≤ 40 GHz
Maximum sweep rate	f ≤ 375 MHz	500 MHz/ms
	375 MHz < f ≤ 750 MHz	31.25 MHz/ms
	750 MHz < f ≤ 1500 MHz	62.5 MHz/ms
	1.5 GHz < f ≤ 3 GHz	125 MHz/ms
	3 GHz < f ≤ 6 GHz	250 MHz/ms
	6 GHz < f ≤ 12 GHz	500 MHz/ms
	12 GHz < f ≤ 24 GHz	1 GHz/ms
	24 GHz < f ≤ 48 GHz	2 GHz/ms
	48 GHz < f ≤ 67 GHz	4 GHz/ms
Frequency accuracy		(0.005 % of span) / (sweep time/s)
Sweep time		
Setting range		10 ms to 100 s
Setting resolution		0.1 ms
Frequency markers	number of frequency markers	10

## List mode

Frequency and level values can be stored in a list and triggered by an internal timer or an external trigger.

Run mode		live
Operating modes	internal trigger, infinite	auto
	internal trigger, one sweep per trigger event	single
	internal trigger, one step per trigger event	step
	external trigger, one sweep per trigger event	extern single
	external trigger, one step per trigger event	extern step
Dwell time setting range	can be set individually for each step	1 ms to 100 s
Dwell time setting resolution		0.1 ms

## **Spectral purity**

Harmonics <sup>3</sup>	CW				
R&S®SMAB-B103/-B106	level = 10 dBm;				
		for instruments equipped with R&S®SMAB-B32 ultra high output power option:			
	level = 18 dBm				
	100 kHz ≤ f ≤ 10 MHz	<-30 dBc			
	f > 10 MHz	<-60 dBc			
R&S®SMAB-B112/-B120	level = 10 dBm:				
	for instruments equipped with R&S	S®SMAB-B34 ultra high output power option:			
	level = 16 dBm				
	100 kHz ≤ f ≤ 10 MHz	<-30 dBc			
	f > 10 MHz	<-55 dBc			
R&S®SMAB-B131/-B140/-B140N/	level = 10 dBm or maximum speci	fied output power, whichever is lower;			
-B150/-B150N/-B167/-B167N		output power option, ultra high output power option			
	or super ultra high output power of				
	100 kHz ≤ f ≤ 10 MHz	< -30 dBc			
	f > 10 MHz	< -55 dBc			
Nonharmonics	CW, offset > 10 kHz from carrier,				
	level = 10 dBm or maximum speci	fied output power, whichever is lower			
	f ≤ 750 MHz	< -96 dBc			
	750 MHz < f ≤ 1.5 GHz	< -92 dBc			
	1.5 GHz < f ≤ 3 GHz	< -86 dBc			
	3 GHz < f ≤ 6 GHz	< -80 dBc			
	6 GHz < f ≤ 12 GHz	<-74 dBc			
	12 GHz < f ≤ 24 GHz	< -68 dBc			
	24 GHz < f ≤ 48 GHz	< -62 dBc			
	f > 48 GHz	< -56 dBc			
	for instruments equipped with R&S®SMAB-B711(N) ultra low phase noise option:				
	CW, offset > 10 kHz from carrier,				
	level = 10 dBm or maximum speci	fied output power, whichever is lower			
	f ≤ 1.5 GHz	<-100 dBc			
	1.5 GHz < f ≤ 3 GHz	<-94 dBc			
	3 GHz < f ≤ 6 GHz	< -88 dBc			
	6 GHz < f ≤ 12 GHz	< -82 dBc			
	12 GHz < f ≤ 24 GHz	< -76 dBc			
	24 GHz < f ≤ 48 GHz	<-70 dBc			
	f > 48 GHz	<-64 dBc			
Subharmonics <sup>4</sup>	CW, level operating mode: auto,				
	level = 10 dBm or maximum speci	fied output power, whichever is lower			
	f≤5 GHz	< -85 dBc,			
		< -95 dBc with R&S®SMAB-B711(N) option			
	5 GHz < f ≤ 20 GHz	<-60 dBc			
	20 GHz < f ≤ 50 GHz	<-60 dBc			
	20 0112 11 2 00 0112	1 00 020			

 $<sup>^{3}</sup>$  Specifications are not valid for harmonics beyond "specified frequency range" or above 50 GHz.

 $<sup>^4</sup>$  Specifications are not valid for subharmonics beyond "specified frequency range" or above 50 GHz.

Wideband noise		level operating mode: auto, measurement bandwidth: 1 Hz, CW; level = 10 dBm or maximum available output power, whichever is lower			
		carrier offset: 10 MHz or 10 % of carrier frequency, whichever is lower			
	f ≤ 8 MHz	< –150 dBc			
	8 MHz < f ≤ 1.5 GHz	< -155 dBc			
	1.5 GHz < f ≤ 3 GHz	< -153 dBc			
	3 GHz < f ≤ 6.0 GHz	< -150 dBc			
	carrier offset: 40 MHz	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1			
	6.0 GHz < f ≤ 12 GHz	< -150 dBc			
	12 GHz < f ≤ 20 GHz	<-145 dBc			
	20 GHz < f ≤ 40 GHz	< -145 dBc (typ.)			
	40 GHz < f ≤ 50 GHz	< –140 dBc (typ.)			
	f > 50 GHz	-142 dBc (meas.)			
		MAB-B711(N) ultra low phase noise option			
		f carrier frequency, whichever is lower			
	f ≤ 8 MHz	< –150 dBc			
	8 MHz < f ≤ 1.5 GHz	< -157 dBc			
	1.5 GHz < f ≤ 3 GHz	<-155 dBc			
	3 GHz < f ≤ 6.0 GHz	< -155 dBc			
	carrier offset: 30 MHz				
	6.0 GHz < f ≤ 12 GHz	< -154 dBc			
	12 GHz < f ≤ 16 GHz	< -152 dBc (typ.)			
	carrier offset: 40 MHz	(71 /			
	16 GHz < f ≤ 20 GHz	< -152 dBc (typ.)			
	20 GHz < f ≤ 40 GHz	< –145 dBc (typ.)			
	40 GHz < f ≤ 50 GHz	< -140 dBc (typ.)			
	f > 50 GHz	-142 dBc (meas.)			
SSB phase noise	for standard instruments or equippe	,			
,		ement bandwidth: 1 Hz, level = 10 dBm or			
	maximum available output power, v				
	f = 10 MHz <sup>5</sup>	< -158 dBc, -165 dBc (typ.)			
	f = 100 MHz	< -154 dBc, -159 dBc (typ.)			
	f = 1 GHz	< -135 dBc, -140 dBc (typ.)			
	f = 2 GHz	< -129 dBc, -134 dBc (typ.)			
	f = 3 GHz	< -125 dBc, -130 dBc (typ.)			
	f = 4 GHz	< -123 dBc, -128 dBc (typ.)			
	f = 6 GHz	< -119 dBc, -124 dBc (typ.)			
	f = 10 GHz	< -115 dBc, -120 dBc (typ.)			
	f = 20 GHz	< -109 dBc, -114 dBc (typ.)			
	f = 40 GHz	< -103 dBc, -108 dBc (typ.)			
	f = 50 GHz	<-101 dBc, -106 dBc (typ.)			
	f = 67 GHz	< -98 dBc, -103 dBc (typ.)			

<sup>5</sup> For instruments equipped with R&S®SMAB-B131/-B140(N)/-B150(N)/-B167(N) frequency options, the specified phase noise values at 10 MHz RF frequency show the typical performance.

### SSB phase noise with R&S®SMAB-B709 option

Specified values in plain text, measured values in brackets () and italics.

SSB phase noise in dBo	SSB phase noise in dBc (1 Hz), CW, level = 10 dBm or maximum available output power, whichever is lower					
Offset frequency	1 Hz	10 Hz	100 Hz	1 kHz		
Carrier frequency						
f = 10 MHz <sup>6</sup>	(–98)	-120	-136	-147		
f = 100 MHz	(–79)	-103	-124	-144		
f = 1 GHz	(–59)	-83	-104	-124		
f = 2 GHz	(–53)	<b>–77</b>	<b>-98</b>	-118		
f = 3 GHz	(–49)	-73	<b>-94</b>	-114		
f = 4 GHz	(–47)	<b>-71</b>	<b>-92</b>	-112		
f = 6 GHz	(-43)	-67	-88	-108		
f = 10 GHz	(-39)	-63	-84	-104		
f = 20 GHz	(–33)	-58	<b>–78</b>	-98		
f = 40 GHz	(–27)	<b>-</b> 52	<del>-7</del> 2	-92		
f = 50 GHz	(–25)	-50	-70	-90		
f = 67 GHz	(–22)	<b>–47</b>	<b>–</b> 67	<del>-</del> 87		

SSB phase noise in dBc (1 Hz), CW, level = 10 dBm or maximum available output power, whichever is lower					
Offset frequency	10 kHz	100 kHz	1 MHz	10 MHz	
Carrier frequency					
f = 10 MHz <sup>6</sup>	<b>–157</b>	-160	<b>–161</b>		
f = 100 MHz	<b>–155</b>	<b>–155</b>	-162	-162	
f = 1 GHz	-140	-138	-145	-160	
f = 2 GHz	-134	-132	-139	-159	
f = 3 GHz	-130	-128	-136	-159	
f = 4 GHz	-128	-126	-133	<b>–157</b>	
f = 6 GHz	-124	-122	<b>–131</b>	-156	
f = 10 GHz	-120	-118	-124	-148	
f = 20 GHz	-114	-112	-118	-142	
f = 40 GHz	-108	-106	-112	-136	
f = 50 GHz	-106	-104	-110	-134	
f = 67 GHz	-103	-101	-107	-131	

<sup>&</sup>lt;sup>6</sup> For instruments equipped with R&S®SMAB-B131/-B140(N)/-B150(N)/-B167(N) frequency options, the specified phase noise values at 10 MHz RF frequency show the typical performance.

### SSB phase noise with R&S®SMAB-B710(N) option

Specified values in plain text, typical values in brackets (), measured values in brackets () and italics. Specifications above 3 GHz only applicable for R&S®SMAB-B710 option.

SSB phase noise in dBo	SSB phase noise in dBc (1 Hz), CW, level = 10 dBm or maximum available output power, whichever is lower					
Offset frequency	1 Hz	10 Hz	100 Hz	1 kHz		
Carrier frequency						
f = 10 MHz <sup>6</sup>	(–116)	-124 (-130)	-136 (-141)	-147 (-154)		
f = 100 MHz	(–101)	-117 (-122)	-129 (-136)	-144 (-152)		
f = 1 GHz	(–82)	-97 (-103)	-111 (-117)	-131 (-139)		
f = 2 GHz	(–76)	<b>–91 (–97)</b>	-105 (-111)	-125 (-132)		
f = 3 GHz	(-72)	-87 (-93)	-101 (-108)	-121 (-129)		
f = 4 GHz	(-70)	-86 ( <del>-</del> 91)	<b>-99 (-106)</b>	-119 (-127)		
f = 6 GHz	(-66)	-81 ( <del>-</del> 87)	-95 (-102)	-115 (-123)		
f = 10 GHz	(-62)	-77 ( <del>-</del> 83)	<b>-91</b> ( <b>-97</b> )	-111 (-119)		
f = 20 GHz	(–56)	-71 ( <del>-</del> 77)	-85 (-91)	-105 (-113)		
f = 40 GHz	(-50)	-65 ( <del>-71</del> )	-79 (-85)	-99 (-107)		
f = 50 GHz	(-47)	-63 (-69)	-77 (-83)	-97 (-104)		
f = 67 GHz	(-44)	-60 (-66)	-74 (-81)	-94 (-102)		

SSB phase noise in dBc (1 Hz), CW, level = 10 dBm or maximum available output power, whichever is lower				
Offset frequency	10 kHz	100 kHz	1 MHz	10 MHz
Carrier frequency				
f = 10 MHz <sup>7</sup>	-157 (-163)	-160 (-165)	-161 (-166)	
f = 100 MHz	-155 ( <del>-</del> 161)	-155 ( <del>-</del> 160)	-162 (-166)	-162 (-169)
f = 1 GHz	-140 (-145)	-138 (-143)	-145 (-150)	-160 (-165)
f = 2 GHz	-134 (-139)	-132 (-137)	-139 (-144)	-159 (-165)
f = 3 GHz	-130 (-135)	-128 (-134)	-136 (-143)	-159 (-165)
f = 4 GHz	-128 (-133)	-126 (-131)	-133 (-138)	-157 (-161)
f = 6 GHz	-124 (-130)	-122 (-129)	-131 (-137)	-156 (-160)
f = 10 GHz	-120 (-125)	-118 (-123)	-124 (-130)	-148 (-153)
f = 20 GHz	-114 (-119)	-112 (-117)	-118 (-124)	-142 (-147)
f = 40 GHz	-108 (-113)	-106 (-111)	-112 (-118)	-136 (-141)
f = 50 GHz	-106 (-111)	-104 (-109)	-110 (-116)	-134 (-139)
f = 67 GHz	-103 (-110)	-101 (-106)	-107 (-113)	-131 (-136)

<sup>&</sup>lt;sup>7</sup> For instruments equipped with frequency options R&S®SMAB-B131/-B140(N)/-B150(N)/-B167(N), the specified phase noise values at 10 MHz RF frequency show the typical performance.

### SSB phase noise with R&S®SMAB-B711(N) option

Specified values in plain text, typical values in brackets (), measured values in brackets () and italics. Specifications above 3 GHz only applicable for R&S $^{\circ}$ SMAB-B711 option.

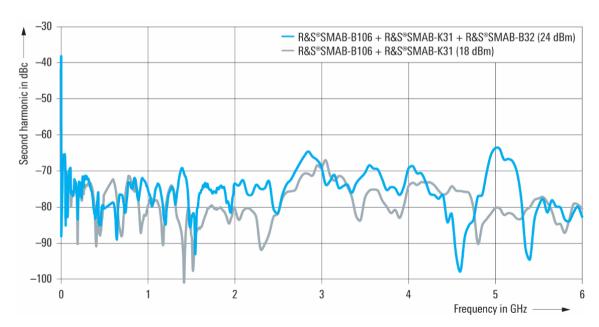
SSB phase noise in dBc (1 Hz), CW, level = 10 dBm or maximum available output power, whichever is lower				
Offset frequency	1 Hz	10 Hz	100 Hz	1 kHz
Carrier frequency				
f = 10 MHz <sup>7</sup>	(–116)	-124 (-130)	-136 (-141)	-147 (-154)
f = 100 MHz	(-101)	-117 (-122)	-129 (-136)	-146 (-152)
f = 1 GHz	(-82)	-97 (-103)	-111 (-117)	-135 (-139)
f = 2 GHz	(–76)	-91 (-97)	-105 (-111)	-129 (-133)
f = 3 GHz	(-72)	-87 (-93)	-101 (-108)	-125 (-130)
f = 4 GHz	(-70)	-86 (-91)	-99 (-106)	-122 (-127)
f = 6 GHz	(-66)	-81 (-87)	-95 (-102)	-119 (-124)
f = 10 GHz	(-62)	-77 (-83)	-91 (-97)	-115 (-120)
f = 20 GHz	(-56)	-71 ( <del>-</del> 77)	-85 (-91)	-109 (-114)
f = 40 GHz	(-50)	-65 ( <del>-71</del> )	-79 (-85)	-103 (-107)
f = 50 GHz	(-47)	-63 (-69)	-77 (-83)	-101 (-105)
f = 67 GHz	(-44)	-60 (-66)	-74 (-81)	-98 (-103)

SSB phase noise in dBo	SSB phase noise in dBc (1 Hz), CW, level = 10 dBm or maximum available output power, whichever is lower				
Offset frequency	10 kHz	100 kHz	1 MHz	10 MHz	
Carrier frequency					
f = 10 MHz <sup>7</sup>	-157 (-163)	-160 (-166)	-161 (-166)		
f = 100 MHz	-155 ( <del>-</del> 161)	-162 (-166)	-162 (-167)	-162 (-168)	
f = 1 GHz	-147 (-151)	-148 (-153)	-157 (-162)	-160 (-165)	
f = 2 GHz	-142 (-145)	-142 (-147)	-151 ( <b>-</b> 158)	-159 (-165)	
f = 3 GHz	-138 (-142)	-138 (-144)	-148 (-157)	-159 (-164)	
f = 4 GHz	-135 (-139)	-136 (-141)	-147 (-152)	-157 (-162)	
f = 6 GHz	-132 (-136)	-132 (-138)	-144 (-151)	-155 ( <del>-</del> 161)	
f = 10 GHz	-128 (-132)	-128 (-134)	-140 (-146)	-156 (-160)	
f = 20 GHz	-122 (-126)	-122 (-128)	-134 (-140)	-148 (-153)	
f = 40 GHz	-115 ( <b>-</b> 119)	-116 (-121)	-128 (-133)	-142 (-146)	
f = 50 GHz	-112 (-116)	-114 ( <del>-</del> 119)	-126 (-129)	(-143) (- <i>145</i> )	
f = 67 GHz	-110 (-114)	-111 (-117)	-123 (-128)	(-140) (-142)	

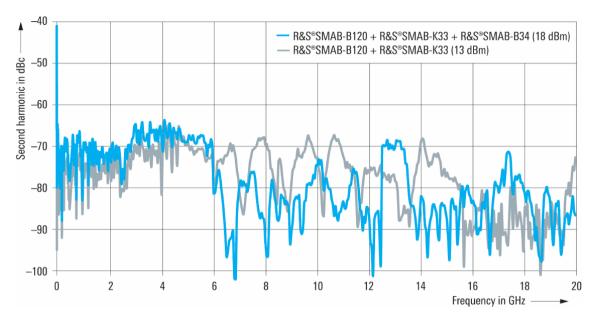
### **RMS** jitter

Specifications above 3 GHz not applicable for R&S®SMAB-B710N and R&S®SMAB-B711N options.

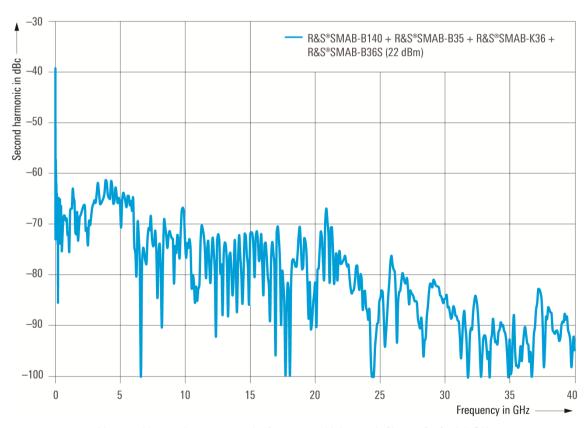
RMS jitter	f = 155 MHz, BW = 100 Hz to 1.5 MHz	20.1 fs (meas.)
	f = 622 MHz, BW = 1 kHz to 5 MHz	18.7 fs (meas.)
	f = 1 GHz, BW = 1 Hz to 10 MHz	558 fs (meas.)
	f = 2.488 GHz, BW = 5 kHz to 20 MHz	18.7 fs (meas.)
	f = 9.952 GHz, BW = 10 kHz to 80 MHz	18.5 fs (meas.)
With R&S®SMAB-B1H option	f = 155 MHz, BW = 100 Hz to 1.5 MHz	19.7 fs (meas.)
·	f = 622 MHz, BW = 1 kHz to 5 MHz	18.8 fs (meas.)
	f = 1 GHz, BW = 1 Hz to 10 MHz	129 fs (meas.)
	f = 2.488 GHz, BW = 5 kHz to 20 MHz	18.7 fs (meas.)
	f = 9.952 GHz, BW = 10 kHz to 80 MHz	18.5 fs (meas.)
With R&S®SMAB-B709 option	f = 155 MHz, BW = 100 Hz to 1.5 MHz	18.5 fs (meas.)
·	f = 622 MHz, BW = 1 kHz to 5 MHz	13.6 fs (meas.)
	f = 1 GHz, BW = 1 Hz to 10 MHz	129 fs (meas.)
	f = 2.488 GHz, BW = 5 kHz to 20 MHz	13.6 fs (meas.)
	f = 9.952 GHz, BW = 10 kHz to 80 MHz	13.1 fs (meas.)
With R&S <sup>®</sup> SMAB-B710(N) option	f = 155 MHz, BW = 100 Hz to 1.5 MHz	18.5 fs (meas.)
	f = 622  MHz,  BW = 1  kHz to 5 MHz	13.6 fs (meas.)
	f = 1 GHz, BW = 1 Hz to 10 MHz	21.3 fs (meas.)
	f = 2.488  GHz, BW = 5 kHz to 20 MHz	13.6 fs (meas.)
	f = 9.952  GHz, BW = 10  kHz to  80  MHz	13.1 fs (meas.)
With R&S®SMAB-B711(N) option	f = 155 MHz, BW = 100 Hz to 1.5 MHz	8.4 fs (meas.)
	f = 622  MHz, BW = 1 kHz to 5 MHz	5.1 fs (meas.)
	f = 1  GHz, $BW = 1  Hz$ to 10 MHz	17.5 fs (meas.)
	f = 2.488  GHz, $BW = 5  kHz$ to 20 MHz	4.1 fs (meas.)
	f = 9.952 GHz, BW = 10 kHz to 80 MHz	3.8 fs (meas.)
Residual FM	RMS values at f = 1 GHz	
	0.3 kHz to 3 kHz, weighted (ITU-T)	< 1 Hz
	0.03 kHz to 23 kHz	< 4 Hz
Residual AM	level = 8 dBm, f ≤ 41 GHz,	< 0.02 %
	RMS value (0.03 kHz to 20 kHz)	



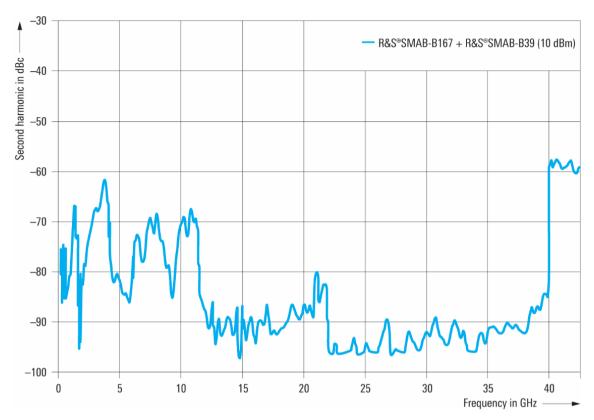
Measured harmonics versus carrier frequency with harmonic filter on for  $f \le 3.7$  GHz



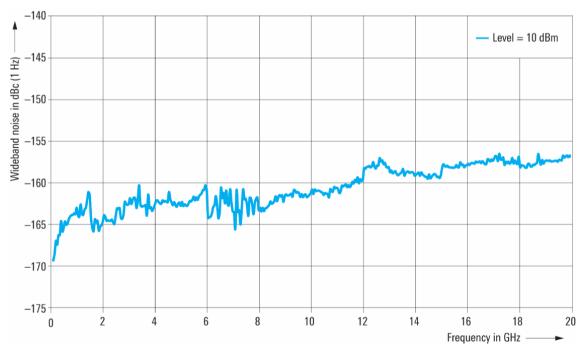
Measured harmonics versus carrier frequency with harmonic filter on for f ≤ 3.7 GHz



Measured harmonics versus carrier frequency with harmonic filter on for  $f \le 3.7$  GHz

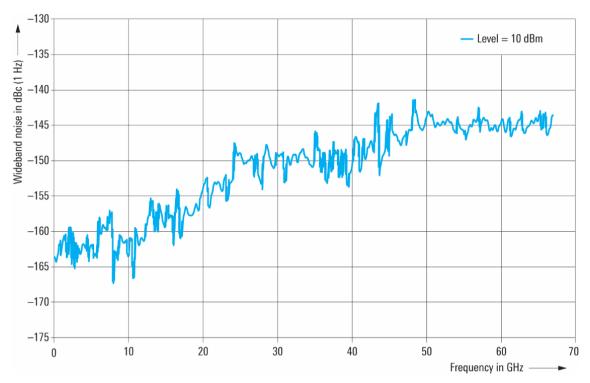


Measured harmonics versus carrier frequency with harmonic filter on for f ≤ 3.7 GHz



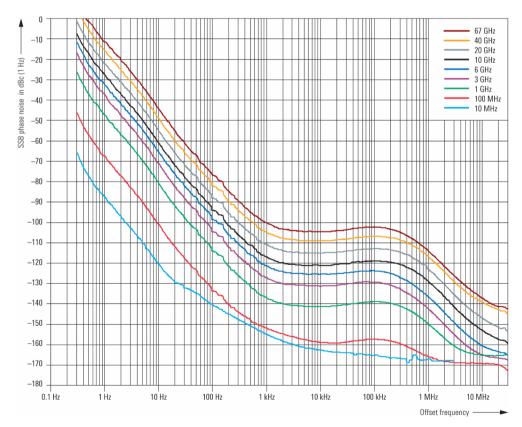
Measured wideband noise at 30 MHz offset and +10 dBm versus carrier frequency with the R&S®SMAB-B120, R&S®SMAB-B711 and R&S®SMAB-B34 options.

Measured with the R&S®FSWP phase noise analyzer

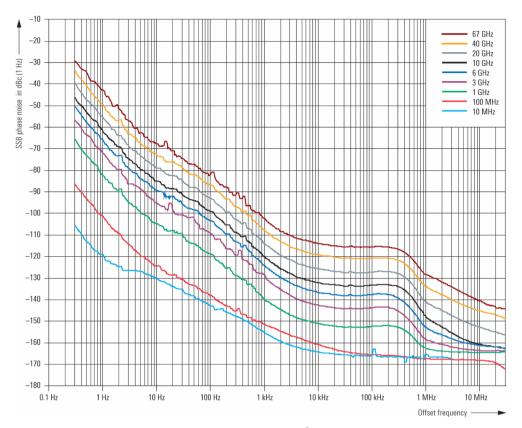


Measured wideband noise at 70 MHz offset and +10 dBm versus carrier frequency with the R&S®SMAB-B167, R&S®SMAB-B711 and R&S®SMAB-B39 options.

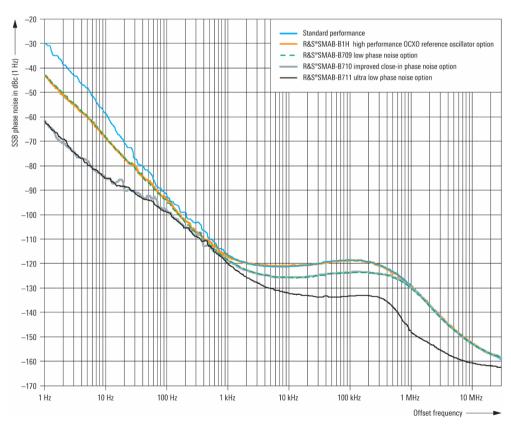
Measured with the R&S®FSW85 spectrum analyzer



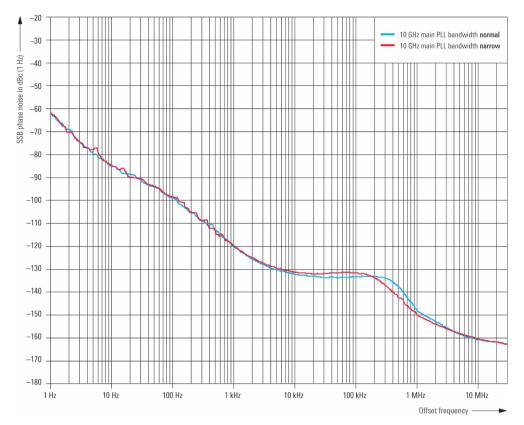
Measured SSB phase noise (standard performance)



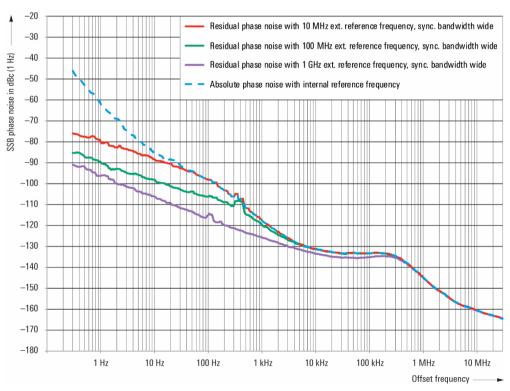
Measured SSB phase noise with the R&S®SMAB-B711(N) option



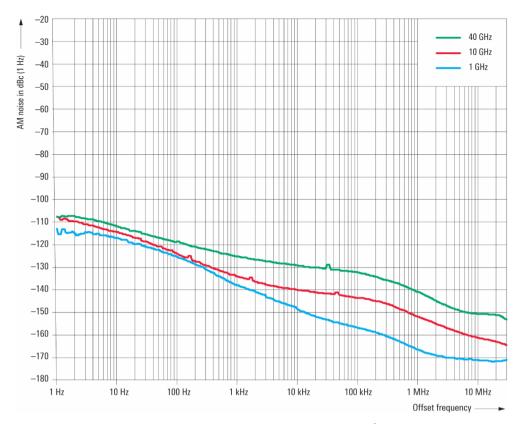
Measured SSB phase noise at f=10 GHz, standard performance versus the R&S®SMAB-B1H, R&S®SMAB-B709, R&S®SMAB-B710 and R&S®SMAB-B711 options



Measured SSB phase noise at f = 10 GHz, comparison of PLL bandwidth normal and narrow with the R&S®SMAB-B711 option



Measured residual SSB phase noise at f = 10 GHz with the R&S®SMAB-B711 option; comparison of different reference frequencies against absolute phase noise



Measured AM noise at f = 1 GHz, 10 GHz and 40 GHz with the R&S®SMAB-B711 option

## **Analog modulation**

## Simultaneous modulation

Can be simultaneously combined with →	AM	Scan AM	FM	φМ	Pulse modulation	Chirped pulses
	0	_	•	_	•	_
AM	0	_	•	_	_	•
AIVI	0	_	_	•	•	_
	0	_	_	•	_	•
	_	0	•	_	•	_
Coop AM	_	0	•	_	_	•
Scan AM	_	0	_	•	•	_
	_	0	_	•	_	•
·						
	•	_	0	_	•	_
FM	•	_	0	_	_	•
FIVI	_	•	0	_	•	_
	_	•	0	_	_	•
	•	_	_	0	•	_
<b>60</b> M	•	_	_	0	_	•
φΜ	_	•	_	0	•	_
	_	•	_	0	_	•
<u>'</u>		'				
	•	_	•	_	_	_
Pulse modulation or	•	_	_	•	_	_
Chirped pulses	_	•	•	_	_	_
	_	•	_	•	_	_

<sup>• =</sup> compatible, - = incompatible,  $\circ$  = compatible with limitations

With certain types of avionics modulation (VOR, ILS, ADF), simultaneous modulation is not possible.

## Amplitude modulation (R&S®SMAB-K720 option)

For f ≥ 100 kHz, attenuator mode: auto, level (PEP) <sup>8</sup> = 10 dBm or maximum available output power, whichever is lower. Level = 15 dBm for instruments equipped with R&S®SMAB-B32/-B34 ultra high output power option. At high levels, modulation is clipped when the maximum PEP is reached.

Modulation source		internal, external, internal + external	
External coupling		AC, DC	
AM type		linear, exponential	
Linear AM depth			
Setting range	internal modulation source	0 % to 100 %	
	external modulation source	0 %/V to 100 %/V	
Setting resolution		0.01 %(/V)	
AM depth (m) error	f <sub>mod</sub> = 1 kHz and m < 80 %	< (3 % of reading + 1 %)	
Exponential AM depth			
Setting range	internal modulation source	0 dB to 30 dB	
	external modulation source	0 dB/V to 30 dB/V	
Setting resolution		0.01 dB(/V)	
AM distortion	$f_{mod} = 1 \text{ kHz}$		
	m = 30 %	< 1 %	
	m = 80 %	< 2 %	
Modulation frequency response	m = 60 %, coupling: DC/AC, input impedance: 50 Ω		
	DC, 10 Hz to 100 kHz	< 3 dB	
Incidental φM at AM	m = 30 %, f <sub>mod</sub> = 1 kHz, ±peak/2		
	f ≤ 15 GHz	< 0.15 rad	
	15 GHz < f ≤ 20 GHz	< 0.2 rad	
	f > 20 GHz	< 0.2 rad (meas.)	

<sup>&</sup>lt;sup>8</sup> PEP = peak envelope power.

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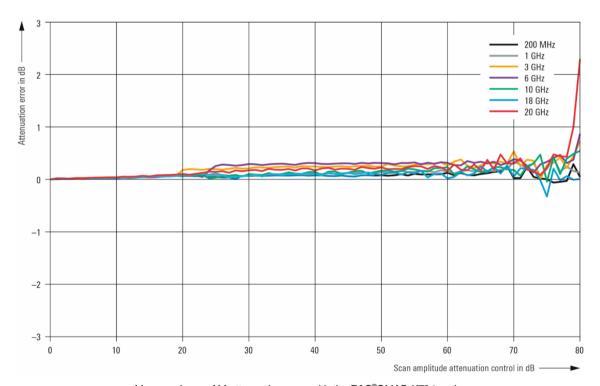
## Scan AM (R&S®SMAB-K721 option)

Level (PEP)  $^{8}$  = 10 dBm or maximum available output power, whichever is lower.

Level = 15 dBm for instruments equipped with R&S®SMAB-B32/-B34/-B35/-B36S/-B37/-B39 ultra high output power option. Scan AM is available for f > 52 MHz.

Prerequisite: R&S®SMAB-K720 option must be installed.

Modulation source		internal, external, internal + external		
External coupling		DC		
Scan AM depth				
Setting range	internal modulation source	0 dB to 100 dB		
	external modulation source	0 to 100 dB/V		
Resolution of setting		0.01 dB		
Maximum attenuation		> 60 dB, 70 dB (typ.)		
Attenuation error	level setting characteristic: auto, temp	level setting characteristic: auto, temperature range from +18 °C to +33 °C		
	specifications are measured for f > 40	specifications are measured for f > 40 GHz		
	0 dB < m ≤ 10 dB	< 0.25 dB		
	10 dB < m ≤ 20 dB	< 1 dB		
	20 dB < m ≤ 40 dB	< 2 dB (typ.)		
	40 dB < m ≤ 50 dB	< 3 dB (typ.)		
	50 dB < m ≤ 60 dB	< 4 dB (typ.)		
Rise/fall time	transition time: 10 % to 90 % (log) for	r < 10 μs (meas.)		
	RF amplitude step of 60 dB			



Measured scan AM attenuation error with the R&S®SMAB-K721 option

# Frequency bands for frequency modulation, phase modulation and chirped pulses

Multiplier N is used to define FM,  $\phi M$  and chirped pulses specifications within this document.

Multiplier (N) for different frequency	FM mode: low noise,				
ranges	φM mode: low noise	φM mode: low noise			
	f ≤ 8 MHz	1/2			
	8 MHz < f ≤ 11.71875 MHz	1/128			
	11.71875 MHz < f ≤ 23.4375 MHz	1/64			
	23.4375 MHz < f ≤ 46.875 MHz	1/32			
	46.875 MHz < f ≤ 93.75 MHz	1/16			
	93.75 MHz < f ≤ 187.5 MHz	1/8			
	187.5 MHz < f ≤ 375 MHz	1/4			
	375 MHz < f ≤ 750 MHz	1/2			
	750 MHz < f ≤ 1.5 GHz	1			
	1.5 GHz < f ≤ 3 GHz	2			
	3 GHz < f ≤ 6 GHz	4			
	6 GHz < f ≤ 12 GHz	8			
	12 GHz < f ≤ 24 GHz	16			
	24 GHz < f ≤ 48 GHz	32			
	48 GHz < f ≤ 67 GHz	64			
	FM mode: high bandwidth,				
	φM mode: high bandwidth, high deviation	n, chirped pulses			
	f ≤ 350 MHz	1/2			
	350 MHz < f ≤ 375 MHz	1/4			
	375 MHz < f ≤ 750 MHz	1/2			
	750 MHz < f ≤ 1.5 GHz	1			
	1.5 GHz < f ≤ 3 GHz	2			
	3 GHz < f ≤ 6 GHz	4			
	6 GHz < f ≤ 12 GHz	8			
	12 GHz < f ≤ 24 GHz	16			
	24 GHz < f ≤ 48 GHz	32			
	48 GHz < f ≤ 67 GHz	64			

## Frequency modulation (R&S®SMAB-K720 option)

Specifications only valid for main PLL bandwidth normal.

Modulation source		internal, external, internal + external	
External coupling		AC, DC	
FM modes		high bandwidth, low noise	
Maximum deviation	FM mode: high bandwidth	N × 10 MHz	
	FM mode: low noise	N × 100 kHz	
Resolution of setting		< 0.02 % of set deviation or N × 0.1 Hz,	
		whichever is greater, min. 0.01 Hz	
FM deviation error	f <sub>mod</sub> = 10 kHz, deviation ≤ half of max. devia	ation or 10 MHz, whichever is lower	
	source: internal	< (1.5 % of reading + 20 Hz)	
	source: external,	< (2 % of reading + 20 Hz)	
	input impedance: high		
FM distortion	$f_{mod} = 10 \text{ kHz}$ , deviation = N × 1 MHz	< 0.1 %	
Modulation frequency response	FM mode: high bandwidth, coupling: DC/AC, input impedance: 50 $\Omega$		
	DC, 10 Hz to 100 kHz	< 0.5 dB	
	f > 350 MHz		
	DC, 10 Hz to 10 MHz	< 3 dB	
	f ≤ 350 MHz		
	DC, 10 Hz to 5 MHz	< 3 dB	
	FM mode: low noise, coupling: DC/AC, input impedance: 50 Ω		
	DC, 10 Hz to 100 kHz	< 3 dB	
Synchronous AM with FM	FM mode: high bandwidth, 40 kHz deviation, f <sub>mod</sub> = 1 kHz		
	8 MHz < f ≤ 3 GHz	< 0.1 %	
	f > 3 GHz	< 0.2 %	
Carrier frequency offset with FM DC	after FM offset calibration, FM source:	< 0.2 % of set deviation	
(external)	external, input impedance 50 Ω		

## Phase modulation (R&S®SMAB-K720 option)

Specifications only valid for main PLL bandwidth normal.

Modulation source		internal, external, internal + external
External coupling		AC, DC
φM modes		high deviation, high bandwidth, low noise
Maximum deviation	φM mode: high deviation	N x 20 rad
	φM mode: high bandwidth	N x 1 rad
	φM mode: low noise	N x 0.25 rad
Resolution of setting	φM modes: high deviation, low noise	< 0.02 % of set deviation or N × 20 μrad, whichever is greater, min. 1 μrad
	φM mode: high bandwidth	< 0.1 % of set deviation,
		min. N × 20 μrad
φM deviation error	f <sub>mod</sub> = 10 kHz, deviation ≤ half of max. de	eviation
	source: internal	< (1.5 % of reading + 0.003 rad)
	source: external,	< (2 % of reading + 0.003 rad)
	input impedance: high	
φM distortion	$f_{mod} = 10 \text{ kHz},$	< 0.2 %, < 0.1 % (typ.)
	deviation = half of max. deviation	
Modulation frequency response	φM mode: high deviation, coupling: DC//	AC, input impedance: 50 Ω
	deviation ≤ N × 5 rad	< 1 dB
	DC, 10 Hz to 500 kHz	
	deviation > N x 5 rad	< 1 dB
	DC, 10 Hz to 10 kHz	
	φM mode: high bandwidth, coupling: DC/AC, input impedance: 50 Ω	
	DC, 10 Hz to 100 kHz	< 1 dB
	f > 350 MHz	
	DC, 10 Hz to 10 MHz	< 3 dB
	f ≤ 350 MHz	
	DC, 10 Hz to 5 MHz	< 3 dB
	φM mode: low noise, coupling: DC/AC, input impedance: 50 $Ω$	
	DC, 10 Hz to 100 kHz	< 3 dB

## Pulse modulation (R&S®SMAB-K22 option)

Modulation source		external
	with R&S®SMAB-K23 option	external, internal
On/off ratio		> 80 dB
Rise/fall time	10 % to 90 % of RF amplitude	
	8 kHz < f ≤ 52 MHz	< 200 ns (meas.)
	52 MHz < f ≤ 700 MHz	< 10 ns, 5 ns (meas.)
	700 MHz < f ≤ 50 GHz	< 10 ns, 5 ns (typ.)
	f > 50 GHz	< 10 ns (meas.)
Minimum pulse width	f > 700 MHz, 50 % / 50 % of RF amplitude	
	R&S®SMAB-B103/-B106/-B112/-B120/ -B131/-B140/-B150/-B167	< 20 ns
	R&S®SMAB-B140N/-B150N/-B167N	30 ns
Pulse repetition frequency		0 Hz to 25 MHz
Video feedthrough	level below 10 dBm or maximum specified level, whichever is lower	
_	f ≤ 6 GHz	< 10 % of RF
	f > 6 GHz	< 10 % of RF,
		< 2 mV (peak-to-peak),
		whichever is lower
Pulse overshoot	f ≤ 40 GHz	< 10 %
	f > 40 GHz	< 10 % (meas.)
Pulse delay	pulse external trigger to RF	
	f ≤ 6 GHz	60 ns (meas.)
	6 GHz < f ≤ 20 GHz	50 ns (meas.)
	f > 20 GHz	45 ns (meas.)
Pulse external trigger input		
Input impedance		10 kΩ or 50 Ω (nom.)
Threshold voltage		0 V to 2.0 V (nom.)
Input polarity		normal, inverse

#### Chirped pulses (R&S®SMAB-K725 option)

Prerequisite: R&S®SMAB-K22 (high performance pulse modulator), R&S®SMAB-K23 (pulse generator) and R&S®SMAB-K720 (AM/FM/φM) options must be installed.

Together with an ideal chirp signal, impairments such as noise, amplitude fluctuations or Doppler drifts can be conveniently added. They are generated using amplitude and frequency modulation on one or more of the additional sources provided by the multifunction generator (R&S®SMAB-K24).

Chirp bandwidth multiplier (N) for different	f ≤ 350 MHz	1/2
frequency ranges	350 MHz < f ≤ 375 MHz	1/4
	375 MHz < f ≤ 750 MHz	1/2
	750 MHz < f ≤ 1.5 GHz	1
	1.5 GHz < f ≤ 3 GHz	2
	3 GHz < f ≤ 6 GHz	4
	6 GHz < f ≤ 12 GHz	8
	12 GHz < f ≤ 24 GHz	16
	24 GHz < f ≤ 48 GHz	32
	48 GHz < f ≤ 67 GHz	64
Modulation source	internal	
Trigger modes	continuous trigger with internal trigger	• auto
	source	<ul> <li>externally triggered</li> </ul>
		<ul> <li>externally gated</li> </ul>
Trigger slope	external trigger signal	positive, negative
Gate polarity	external gate signal	normal, inverse
Input impedance	external trigger/gate signal	50 Ω, 10 kΩ (nom.)
Chirp direction		up, down
Maximum bandwidth		N × 20 MHz
Pulse period setting range		1.0 µs to 100 s
Pulse width setting range		100 ns to 100 s,
		pulse width < (pulse period – 600 ns)
Pulse parameter setting resolution		5 ns
Maximum chirp rate		$N \times 20 \text{ MHz/}\mu\text{s} \text{ (nom.)}$

#### VOR modulation (R&S®SMAB-K25 option)

Attenuator mode AUTO, level (PEP) <sup>9</sup> within specified level range. VOR specification valid for carrier frequency range from 108 MHz to 118 MHz.

VOR operating modes	generation of VOR signal	NORM
	30 Hz VAR tone	VAR
	9.96 kHz carrier, unmodulated	subcarrier
	9.96 kHz carrier, modulated	subcarrier + FM
Modulation tones		
Frequency error	30 Hz (VAR, REF)	< (0.001 Hz + relative deviation of
		reference frequency × 30 Hz)
Frequency setting range	30 Hz REF	10 Hz to 60 Hz
	9.96 kHz FM carrier	5 kHz to 15 kHz
	COM/ID tone	0.1 Hz to 20 kHz
Frequency setting resolution		0.1 Hz
FM deviation setting range	9.96 kHz FM carrier	0 Hz to 960 Hz
FM deviation setting resolution	9.96 kHz FM carrier	1 Hz
FM deviation error	9.96 kHz FM carrier at 480 Hz deviation	< 1 Hz
External AM tone	input connector	Ext 1
Modulation depth		
Sum of modulation depths of 30 Hz (VAR) s	signal, 9.96 kHz FM carrier, COM/ID and exte	rnal AM signal must not exceed 100 %.
AM depth setting range		0 % to 100 %
AM depth setting resolution		0.1 %
AM depth error	30 Hz (VAR, REF), 30 % AM depth	< 0.5 % AM depth
	9.96 kHz FM carrier, 30 % AM depth	< 0.5 % AM depth
	COM/ID, tone = 1020 Hz, depth = 10 %	< 0.5 % AM depth
External AM tone	sensitivity	0.01 V/%

<sup>&</sup>lt;sup>9</sup> PEP = peak envelope power.

Bearing angle			
Setting range		0° to 360°	
	default setting	0.00°	
Setting resolution		0.01°	
Error		< 0.05°	

#### ILS modulation (R&S®SMAB-K25 option)

Attenuator mode AUTO, level (PEP) <sup>9</sup> within specified level range. ILS-LOC specification valid for carrier frequency range from 108 MHz to 118 MHz. ILS-GS specification valid for carrier frequency range from 329 MHz to 335 MHz.

ILS modulation	generation of ILS localizer signal, COM/ID tone possible	ILS-LOC
	generation of ILS glideslope signal	ILS-GS
ILS operating modes	NORM	90 Hz + 150 Hz + COM/ID tone (ILS-LOC)
120 operating modes	90 Hz	suppression of 150 Hz modulation tone
	150 Hz	suppression of 90 Hz modulation tone
ILS modulation tones	130 112	suppression of 90 Hz modulation tone
	Hz tone is varied, the other tone is automatically ch	nanged in proportion
Frequency error	The toric to variou, the ether terie to automatically or	< (0.02 Hz + relative deviation of
requestoy error		reference frequency × ILS tone frequency)
Frequency setting range	90 Hz tone	60 Hz to 120 Hz
requestoy setting range	150 Hz tone	100 Hz to 200 Hz
	COM/ID tone	0.1 Hz to 20 kHz
Frequency setting resolution	90 Hz tone	0.3 Hz
requeries setting resolution	150 Hz tone	0.5 Hz
	COM/ID tone	0.1 Hz
External AM tone	input connector	Ext 1
Modulation depth	input connector	LXLI
	150 Hz, COM/ID and external AM signal must not	exceed 100 %
Setting range	SDM of 90 Hz, 150 Hz, COM/ID tone	0 % to 100 %
2 cm. ig cm. ig c	ILS-LOC default setting	40 %
	ILS-GS default setting	80 %
Setting resolution	SDM and COM/ID depth	0.1 %
AM depth error	SDM = 40 %	< 0.8 % AM depth
	SDM = 80 %	< 1.6 % AM depth
	COM/ID, tone = 1020 Hz, depth = 10 %	< 0.5 % AM depth
External AM tone	sensitivity	0.01 V/%
Difference in depth of modulation	7	
Setting range		0 to ±SDM
Setting resolution		0.0001
Error		< 0.0003 + 2 % of set DDM
ILS phase	·	,
Setting range		0° to 120°
Setting resolution		0.01°

## Marker beacon (MKR BCN) (R&S®SMAB-K25 option)

Attenuator mode AUTO, level (PEP) within specified level range.

MKR-BCN specification valid for carrier frequency range from 74 MHz to 76 MHz.

Marker beacon modulation tones		
Frequency error		< (0.001 Hz + relative deviation of
		reference frequency × marker frequency)
Marker frequencies		400 Hz, 1300 Hz and 3000 Hz
COM/ID tone frequency setting range	je –	0.1 Hz to 20 kHz
COM/ID tone frequency setting reso	lution	0.1 Hz
Marker beacon modulation depth		
Sum of modulation depths of marke	r tone and COM/ID signal must not exceed 1	00 %.
AM depth setting range		0 % to 100 %
	marker tone default setting	95 %
AM depth setting resolution		0.1 %
AM depth error	marker tone	< 4 % AM depth
	COM/ID, tone = 1020 Hz	< 0.5 % AM depth

## ADF mode (R&S®SMAB-K25 option)

The ADF mode provides a carrier frequency of 190 kHz with 30 % AM depth at 1 kHz modulation rate.

Frequency error	ADF tone	< (0.001 Hz + relative deviation of reference frequency × ADF frequency)
ADF frequency setting range		0.1 Hz to 20 kHz
ADF setting resolution		0.1 Hz
AM depth setting range		0 % to 100 %
AM depth setting resolution		0.1 %
_	ADF tone default setting	30 %

#### Sources for analog modulation

#### Modulation sources for AM, Scan AM, FM and φM

3 different modulation sources are available as modulation signals:

- Internal modulation generator (standard feature)
- Multifunction generator (R&S®SMAB-K24 option)
- · External modulation signals

The AM or Scan AM and FM or  $\phi$ M modulation sources 1 and 2 can be selected individually or simultaneously. The LF generators 1 and 2 and the noise generator are part of the multifunction generator (R&S®SMAB-K24 option).

AM or Scan AM		
Modulation source 1 <sup>10</sup> Modulation source 2 <sup>1</sup>		
LE ganaratar 1	LE gaparatar 1	
LF generator 1 LF generator 2	LF generator 1 LF generator 2	
Noise	Noise	
External 1	External 1	
External 2	External 2	

FM or	φМ
Modulation source 1 10	Modulation source 2 10
LF generator 1	LF generator 1
LF generator 2	LF generator 2
Noise	Noise
External 1	External 1
External 2	External 2

#### Internal modulation generator

Signal types		sine
Frequency setting range		0.1 Hz to 1 MHz
Frequency setting resolution		0.01 Hz
Frequency error		< (0.001 Hz + relative deviation of
		reference frequency × modulation
		frequency)
Frequency response	up to 1 MHz	< 0.3 dB
Distortion	f < 100 kHz,	< 0.1 %
	at $R_L \ge 50 \Omega$ , level $(V_{EMF})$ : < 1 V	

#### Multifunction generator (R&S®SMAB-K24 option)

Signal types	LF generator 1	sine, square, pulse, triangle, trapezoid
	LF generator 2	sine, square, pulse, triangle, trapezoid
	noise generator	Gaussian, uniform
	(noise amplitude distribution)	
Frequency range	sine	0.1 Hz to 10 MHz
	square	0.1 Hz to 1 MHz
	pulse, triangle, trapezoid	0.01 Hz to 1 MHz (displayed value)
	noise bandwidth	100 kHz to 10 MHz
Resolution of setting	sine, square	0.01 Hz
	pulse, triangle, trapezoid	10 ns
	noise bandwidth	100 kHz
Frequency error	sine	< (0.001 Hz + relative deviation of
		reference frequency × modulation
		frequency)
Frequency response	sine, up to 1 MHz	< 0.3 dB
	sine, up to 10 MHz	< 1 dB
Distortion	f < 100 kHz,	< 0.1 %
	at $R_L \ge 50 \Omega$ , level ( $V_{EMF}$ ): 1 V	

<sup>&</sup>lt;sup>10</sup> One out of five sources can be selected.

## LF frequency sweep

Operating mode		digital sweep in discrete steps
Trigger modes	execute sweep continuously with internal	auto
	trigger source	
	execute one full sweep	single
	execute one step	step
	sweep start and stop controlled by	start/stop
	external trigger signal	
Trigger source		external trigger signal (INST TRIG
		at rear), rotary knob, touch panel,
		remote control
Sweep range		full frequency range
Sweep shape		sawtooth, triangle
Step size setting resolution	linear	0.1 Hz
	logarithmic	0.01 %
Dwell time setting range		3 ms to 100 s
Dwell time setting resolution		0.1 ms

## LF output

Monitoring of resulting modulation signal for		AM, FM, φM
Source		LF generator 1, LF generator 2, noise generator, external 1, external 2
Output voltage	V <sub>peak</sub> at LF connector, open-circuit voltage EMF	
Setting range	1 mV to 4 V	
Setting resolution		1 mV
Setting error	$f = 1 \text{ kHz}, R_L > 50 \text{ k}\Omega$	< (1 % of reading + 1 mV)
Output impedance		50 Ω (nom.)

# Pulse generator (R&S®SMAB-K23 option)

Pulse modes		single pulse, double pulse
Trigger modes	free run, internally triggered	auto
		external trigger
		external gate
Pulse period		
Setting range		20 ns to 100 s
Setting resolution		5 ns
Pulse width	pulse widths of double pulses can b	e set independently
Setting range		5 ns to 100 s
Setting resolution		5 ns
Pulse delay		
Setting range		0 s to 100 s
Setting resolution		5 ns
Double-pulse spacing		
Setting range		10 ns to 100 s
Setting resolution		5 ns
External trigger		
Delay	trigger to video output	40 ns (nom.)
Jitter		< 5 ns (nom.)

## Pulse train (R&S®SMAB-K27 option)

The R&S®SMAB-K27 option extends the functionality of the pulse generator (R&S®SMAB-K23 option). With this option, pulses and sequences of pulses can be user-defined in order to generate jittered or staggered pulse scenarios widely used in radar applications.

Prerequisite: R&S®SMAB-K23 option must be installed.

Pulse mode	user-settable pulse width, pulse spacing	train
	and pulse sequences	
Trigger modes	free run, internally triggered	auto
		external trigger
Number of bursts		1 to 2047
Number of identical pulses per burst		1 to 65535
Pulse on time setting range		0 ns to 5 ms
Pulse off time setting range		5 ns to 5 ms
Pulse on and off time setting resolution		5 ns

#### Pulse generator outputs

SYNC output	output of a synchronizing pulse at	output of a synchronizing pulse at pulse start or start of pulse sequence	
Connector type	PULSE SYNC output	BNC female	
SYNC output level	·	digital signal with 0 V/4.2 V (nom.) with no	
		load, source resistance: $R_S = 50 \Omega$ (nom.),	
		load impedance: R <sub>L</sub> ≥ 50 Ω	
SYNC pulse width		5 ns (nom.)	
VIDEO output	output of pulse generator signal	output of pulse generator signal	
Connector type	PULSE VIDEO output	BNC female	
VIDEO output level		digital signal with 0 V/4.2 V (nom.) with no	
		load, source resistance: $R_S = 50 \Omega$ (nom.),	
		load impedance: R <sub>L</sub> ≥ 50 Ω	

## **Additional performance options**

#### Differential clock synthesizer (R&S®SMAB-B29 option)

The R&S®SMAB-B29 option provides a differential or single-ended clock signal with selectable waveform and DC offset up to 3 GHz or up to 6 GHz with the R&S®SMAB-K722 option.

The R&S®SMAB-K722 option is not available for instruments equipped with the 3 GHz R&S®SMAB-B103 RF frequency option. The frequency of the clock synthesizer (R&S®SMAB-B29 option) can be set independently of the RF frequency of the R&S®SMAB100A.

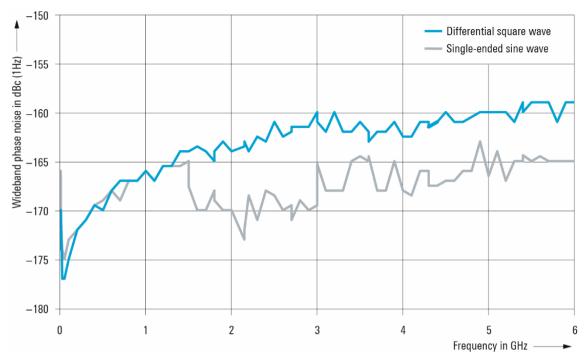
Specifications above 3 GHz are only valid for instruments equipped with the R&S®SMAB-K722 option.

Output types		differential square wave,
Output types		differential sine wave,
		single-ended sine wave,
		differential CMOS
Frequency		amerential emee
Frequency range	differential square wave,	100 kHz to 3 GHz
requests, range	single-ended sine wave	100 M 12 10 0 0 1 12
	differential sine wave	10 MHz to 3 GHz
	with R&S®SMAB-K722 option	10 MHz to 6 GHz
	differential square wave, single-ended	100 kHz to 6 GHz
	sine wave	
	differential sine wave	10 MHz to 6 GHz
	CMOS output	100 kHz to 200 MHz
Resolution of setting		0.001 Hz
Resolution of synthesis	f = 1 GHz	0.053 nHz (nom.)
Frequency setting time	to within $< 1 \times 10^{-7}$ for f > 10 MHz,	< 1.5 ms
Troquency county unic	with GUI update stopped	11.0 11.0
	after IEC/IEEE bus delimiter with	
	R&S®SMAB-B86 option	
Level		1
Level setting range	sine wave, differential and single-ended	-24 dBm to 20 dBm
zoro: county range	differential square wave	fixed
	differential CMOS	0.8 V to 2.7 V
Output connectors	differential evides	0.0 1 to 2.7 1
Connector type	CLK SYN, CLK SYN_N outputs	SMA female
Commoder type	with R&S®SMAB-B93 option (3 HU)	front panel
	with R&S®SMAB-B92 option (2 HU) or	rear panel
	with R&S®SMAB-B93 option (3 HU) and	l can pane.
	R&S®SMAB-B80/-B81/-B82 rear panel	
	connector option	
Reverse power	•	
Reverse power (from 50 Ω source)	maximum permissible RF power	0.05 W
Maximum permissible DC voltage	sine wave and square wave, DC offset disabled	±5 V
	any output type with DC offset enabled	0 V (short-circuit-proof)
DC offset	differential CMOS	0 V (short-circuit-proof)
DC offset Setting range		
Setting range	differential CMOS	0 V (short-circuit-proof)
	differential CMOS	0 V (short-circuit-proof)  -5 V to +5 V
Setting range Setting resolution DC offset source impedance	differential CMOS	0 V (short-circuit-proof)  -5 V to +5 V 1 mV
Setting range Setting resolution	not available in CMOS mode	0 V (short-circuit-proof)  -5 V to +5 V 1 mV 50 Ω (nom.)
Setting range Setting resolution DC offset source impedance Spectral purity	offset > 10 kHz from carrier, level = 10 dBm	0 V (short-circuit-proof)  -5 V to +5 V 1 mV 50 Ω (nom.)
Setting range Setting resolution DC offset source impedance Spectral purity	offset > 10 kHz from carrier, level = 10 dBm	0 V (short-circuit-proof)  -5 V to +5 V 1 mV 50 Ω (nom.)  n, sine wave < -90 dBc
Setting range Setting resolution DC offset source impedance Spectral purity	offset > 10 kHz from carrier, level = 10 dBm	0 V (short-circuit-proof)  -5 V to +5 V 1 mV 50 Ω (nom.)
Setting range Setting resolution DC offset source impedance Spectral purity	differential CMOS  not available in CMOS mode  offset > 10 kHz from carrier, level = 10 dBm $f \le 10$ MHz $10$ MHz < $f \le 750$ MHz $750$ MHz < $f \le 1.5$ GHz	O V (short-circuit-proof)  -5 V to +5 V  1 mV  50 Ω (nom.)  n, sine wave  < -90 dBc  < -96 dBc  < -92 dBc
Setting range Setting resolution DC offset source impedance Spectral purity	offset > 10 kHz from carrier, level = 10 dBm f ≤ 10 MHz 10 MHz < f ≤ 750 MHz 750 MHz < f ≤ 1.5 GHz 1.5 GHz < f ≤ 3 GHz	O V (short-circuit-proof)  -5 V to +5 V  1 mV  50 Ω (nom.)  n, sine wave  < -90 dBc  < -96 dBc  < -92 dBc  < -86 dBc
Setting range Setting resolution DC offset source impedance Spectral purity	differential CMOS  not available in CMOS mode  offset > 10 kHz from carrier, level = 10 dBm $f \le 10$ MHz  10 MHz < $f \le 750$ MHz  750 MHz < $f \le 1.5$ GHz  1.5 GHz < $f \le 3$ GHz  3 GHz < $f \le 6$ GHz	0 V (short-circuit-proof)  -5 V to +5 V 1 mV 50 Ω (nom.)  n, sine wave < -90 dBc < -96 dBc < -92 dBc < -86 dBc < -80 dBc
Setting range Setting resolution DC offset source impedance Spectral purity	differential CMOS  not available in CMOS mode  offset > 10 kHz from carrier, level = 10 dBm $f \le 10$ MHz  10 MHz < $f \le 750$ MHz  750 MHz < $f \le 1.5$ GHz  1.5 GHz < $f \le 3$ GHz  3 GHz < $f \le 6$ GHz instruments equipped with R&S®SMAB-B70	0 V (short-circuit-proof)  -5 V to +5 V 1 mV 50 Ω (nom.)  n, sine wave < -90 dBc < -96 dBc < -92 dBc < -86 dBc < -80 dBc 09/-B710(N)/-B711(N)
Setting range Setting resolution DC offset source impedance Spectral purity	differential CMOS  not available in CMOS mode  offset > 10 kHz from carrier, level = 10 dBm $f \le 10$ MHz  10 MHz < $f \le 750$ MHz  750 MHz < $f \le 1.5$ GHz  1.5 GHz < $f \le 3$ GHz  3 GHz < $f \le 6$ GHz	0 V (short-circuit-proof)  -5 V to +5 V 1 mV 50 Ω (nom.)  n, sine wave < -90 dBc < -96 dBc < -92 dBc < -86 dBc < -80 dBc

Subharmonics 11	level = 10 dBm, sine wave			
	f≤3 GHz	<-94 dBc		
	3 GHz < f ≤ 6 GHz	< -88 dBc		
Wideband noise	maximum output level, sine wave, carrier of			
	measurement bandwidth: 1 Hz	,		
		carrier offset: 10 MHz or 10 % of carrier frequency, whichever is lower		
	f ≤ 8 MHz	< –150 dBc		
	8 MHz < f ≤ 1.5 GHz	< -155 dBc		
	1.5 GHz < f ≤ 3 GHz	< -153 dBc		
	carrier offset: 30 MHz	100 dB0		
	3 GHz < f ≤ 6.0 GHz	< -150 dBc		
	instruments equipped with R&S®SMAB-B7			
	carrier offset: 10 MHz or 10 % of carrier			
	f ≤ 8 MHz	< -150 dBc		
	8 MHz < f ≤ 1.5 GHz	< -157 dBc		
	1.5 GHz < f ≤ 3 GHz	< –155 dBc		
	carrier offset: 30 MHz	4 ID		
	3 GHz < f ≤ 6.0 GHz	< –155 dBc		
SSB phase noise	single-ended and differential sine wave or			
	carrier offset: 20 kHz, measurement bandw			
	f = 10 MHz	< -163 dBc, -168 dBc (typ.)		
	f = 100 MHz	< -155 dBc, -162 dBc (typ.)		
	f = 1 GHz	< -135 dBc, -142 dBc (typ.)		
	f = 2 GHz	< -129 dBc, -136 dBc (typ.)		
	f = 3 GHz	< -125 dBc, -133 dBc (typ.)		
	f = 4 GHz	< -123 dBc, -130 dBc (typ.)		
	f = 6 GHz	< -119 dBc, -126 dBc (typ.)		
	instruments equipped with R&S®SMAB-B709/-B710(N)/-B711(N)			
	f = 10 MHz	< -163 dBc, -168 dBc (typ.)		
	f = 100 MHz	< -158 dBc, -164 dBc (typ.)		
	f = 1 GHz	< -141 dBc, -145 dBc (typ.)		
	f = 2 GHz	< -135 dBc, -139 dBc (typ.)		
	f = 3 GHz	< -131 dBc, -135 dBc (typ.)		
	f = 4 GHz	< -129 dBc, -133 dBc (typ.)		
	f = 6 GHz	< -125 dBc, -130 dBc (typ.)		
RMS jitter	single-ended and differential sine wave or differential square wave			
· ····································	f = 155 MHz, BW = 100 Hz to 1.5 MHz	18.3 fs (meas.)		
	f = 622 MHz, BW = 1 kHz to 5 MHz	18.0 fs (meas.)		
	f = 1 GHz, BW = 1 Hz to 10 MHz	558 fs (meas.)		
	f = 2.488 GHz, BW = 5 kHz to 20 MHz	18.0 fs (meas.)		
	instruments equipped with R&S®SMAB-B7	,		
	f = 155 MHz, BW = 100 Hz to 1.5 MHz	13.6 fs (meas.)		
	f = 622 MHz, BW = 100 Hz to 1.5 MHz	13.7 fs (meas.)		
	·			
	f = 1 GHz, BW = 1 Hz to 10 MHz	129 fs (meas.)		
	f = 2.488 GHz, BW = 5 kHz to 20 MHz	13.6 fs (meas.)		
	instruments equipped with R&S®SMAB-B7			
	f = 155 MHz, BW = 100 Hz to 1.5 MHz	13.6 fs (meas.)		
	f = 622 MHz, BW = 1 kHz to 5 MHz	13.7 fs (meas.)		
	f = 1 GHz, BW = 1 Hz to 10 MHz	21.6 fs (meas.)		
	f = 2.488  GHz, BW = 5 kHz to 20 MHz	13.7 fs (meas.)		

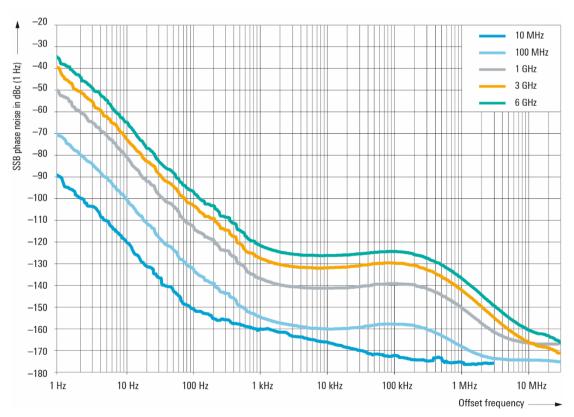
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 $<sup>^{\</sup>rm 11}\,$  Specifications are not valid for subharmonics beyond "specified frequency range".

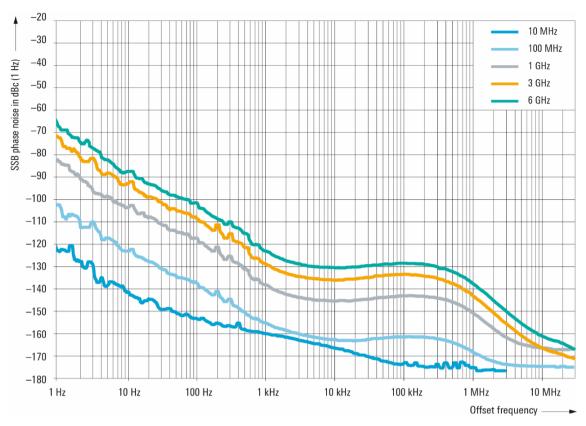


Measured wideband noise of clock synthesizer output at maximum output power versus carrier frequency with the R&S®SMAB-B29 and R&S®SMAB-K722 options.

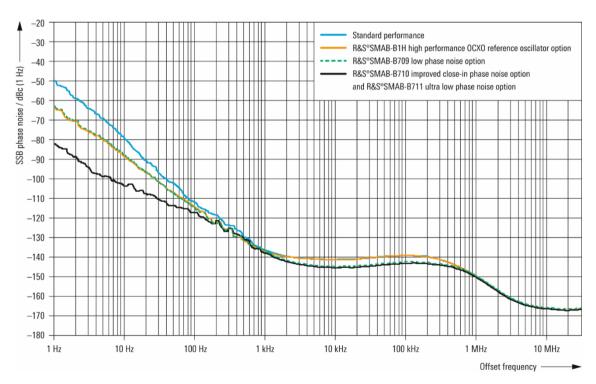
Measured with the R&S®FSWP phase noise analyzer



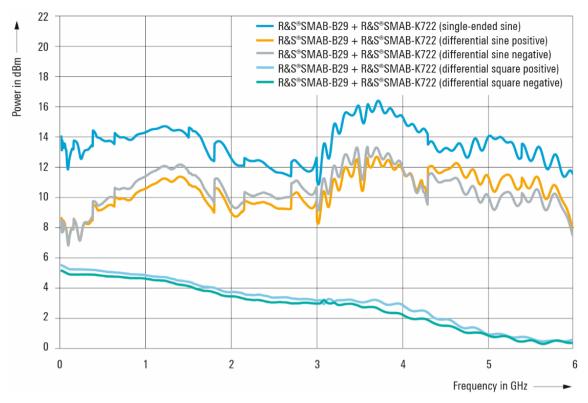
Measured SSB phase noise of clock synthesizer (standard performance) with the R&S®SMAB-B29 and R&S®SMAB-K722 options



Measured SSB phase noise of clock synthesizer with the R&S®SMAB-B29, R&S®SMAB-B711(N) and R&S®SMAB-K722 options



Measured SSB phase noise of clock synthesizer at f=1 GHz, standard performance versus the R&S®SMAB-B1H, R&S®SMAB-B709, R&S®SMAB-B710(N) and R&S®SMAB-B711(N) options



Measured maximum available output power versus frequency for the R&S®SMAB-B29 and R&S®SMAB-K722 options

#### R&S®NRP-Z power analysis (R&S®SMAB-K28 option)

#### Overview of supported power sensor and functionalities

Latest power sensor firmware version is recommended.

Power sensor	Power versus frequency and	Power versus time	Pulse data measurement
	power versus power		
R&S®NRP-Z81/-Z85/-Z86	•	•	•

• = supported, - = not supported.

Modes		power versus frequency
		<ul> <li>power versus power</li> </ul>
		<ul> <li>power versus time (trace mode)</li> </ul>
General settings		
Number of points per sweep (= steps)		10 to 1000
Frequency range	depending on R&S®NRP-Zxx power	full frequency range of signal generator or
	sensor and R&S®SMA100B frequency	power sensor (whichever is lower);
	option	support of frequency-converting DUTs
Y-axis setting range		-200 dBm to +100 dBm
Uncertainty of measured power	determined by power sensor used and	see R&S®NRP data sheet
	timing mode (noise)	(PD 3607.0852.22)
Sweep mode		• single
		continuous
Number of traces	used for sensor data or as reference trace	4
Number of markers		4
Trace data export	supported file formats	JPG, BMP, XPM, PNG, CSV
Resolution of saved graphic file	for JPG, BMP, XPM and PNG file format	800 x 480 pixel (size of screen)

Power versus frequency mode		
Spacing		linear, logarithmic
Timing mode		fast, normal
Sweep time	depends on timing mode, number of steps	set automatically
eweep time	and power sensor	oot automatioany
	e.g. R&S <sup>®</sup> NRP-Z81	approx. 2.5 s
	timing mode FAST, 200 steps	αρρίολ. 2.0 3
Power versus power mode	timing mode i 7.0 i, 200 steps	
Spacing Space Thouse		dB steps
Timing mode		fast, normal
Sweep time	depends on timing mode, steps and	set automatically
Sweep time	power sensor	Set automatically
	e.g. R&S®NRP-Z81	approx. 2.5 s
	timing mode FAST, 200 steps	арргох. 2.3 \$
Power versus time made (trace made)	tilling mode i AST, 200 steps	
Power versus time mode (trace mode)		linear
Spacing	D 0 0®NDD 704 / 705 / 700	iliteat
Sweep time	R&S®NRP-Z81/-Z85/-Z86	100 no to 1 o
	setting range	100 ns to 1 s
	resolution	12.5 ns
	(sweep time/steps) ≥ 12.5 ns	
	resolution	2 ns
	(sweep time/steps) < 12.5 ns,	
	periodic signals,	
	trigger mode internally triggered	
Trace offset	with reference to trigger event	positive, negative
Average		1 to 1024
Trigger modes	internally triggered	auto, free run, internal
	externally triggered,	external
	R&S®NRP-Z3 required	
Trigger level setting range	depends on power sensor used	see R&S®NRP data sheet
		(PD 3607.0852.22)
Trigger hysteresis setting range		0 dB to 10 dB
Trigger dropout time setting range		0 ns to 10 s
Available measurements in time mode		
Gate function		
Number of gates	user-selectable	2
Power measurements		peak power, average power
Pulse data measurement, only with R&S®N	NRP-Z81/-Z85/-Z86	
Timing measurements		duty cycle, pulse width, pulse period,
		pulse off time, rise time, pulse start time,
		overshoot, fall time, pulse stop time
Power measurements		peak power, average power, minimal
		power, top power, base power, distal
		nower model newer provimal newer
		power, mesial power, proximal power
Setting range for distal, mesial and	voltage or power-related	0 % to 100 %

## **Remote control**

Interfaces/systems	standard	Ethernet/LAN 10/100/1000BASE-T
	with R&S®SMAB-B86 option	IEC 60625 (GPIB IEEE-488.2),
		USB 2.0 (according to VISA USB-TMC),
Common de est		serial (RS-232) 12
Command set	These command acts are be acted.	SCPI 1999.5 or compatible command sets
Compatible command sets	These command sets can be selected in	Hewlett Packard
	order to emulate another instrument.  A subset of common commands is	<ul><li>HP 8340, HP 8341</li><li>HP 8360</li></ul>
		<ul> <li>HP 83620, HP 83622, HP 83623,</li> </ul>
	supported. For each emulated instrument, the *IDN?	HP 83624
	and *OPT? strings can be configured to	HP 83630, HP 83640, HP 83650
	meet the specific requirements. This is	• HP 8373
	particularly useful for the	• HP 83711, HP 83712
	Aeroflex/IFR/Marconi instruments since	• HP 83731, HP 83732
	the manufacturer ID changed over time	HP 8642, HP 8643, HP 8644, HP 8645
	and for the Hewlett-Packard/Agilent	• HP 8647, HP 8648
	instruments to adapt to a specific suffix	• HP 8656, HP 8657
	and configuration.	• HP 8662, HP 8663, HP 8664, HP 8665
		• HP 8673
		Agilent/Keysight Technologies
		• E4421, E4422, E4428
		• E8257, E8663
		• N5161, N5181, N5183
		• N5171, N5173
		Aeroflex (IFR/Marconi)
		• 2023, 2024
		• 2030, 2031, 2032
		• 2040, 2041, 2042
		Anritsu
		• 68017, 68037
		Panasonic
		• VP-8303A
		Racal Dana
		• 3102, 9087
		Rohde & Schwarz
		R&S®SMA100A
		<ul> <li>R&amp;S®SME02/03/06</li> </ul>
		• R&S®SMF100A
		R&S®SMG/SMH
		R&S®SMGU/SMHU  R&SWMU  R&SWMU  R&SWMU R&SW
		• R&S®SML01/02/03
		<ul> <li>R&amp;S®SMP02/03/04</li> <li>R&amp;S®SMR20/27/30/40</li> </ul>
		<ul> <li>R&amp;S®SMR20/27/30/40</li> <li>R&amp;S®SMT02/03/06</li> </ul>
		• R&S*SM102/03/06 • R&S*SMY01/02
IEC/IEEE bus address		0 to 30
Ethernet/LAN protocols and services		VISA VXI-11 (remote control)
		Telnet/RawEthernet (remote control)
		VNC (remote operation with web
		browser)
		FTP (file transfer protocol)
		SMB (mapping parts of the instrument)
		to a host file system)
Ethernet/LAN addressing		DHCP, static;
		support of ZeroConf and M-DNS to
		facilitate direct connection to a system
		controller

<sup>&</sup>lt;sup>12</sup> Requires the R&S®TS-USB1 serial adapter (recommended extra).

#### **Connectors**

All digital inputs and outputs are CMOS 3.3 V unless otherwise noted. The input damage level is below –0.5 V or above +5 V.

#### Front or rear panel connectors

These connectors are located either on the front or the rear panel of the instrument, depending on the option configuration.

Model with 2 HU (equipped with the R&S $^{\circ}$ SMAB-B92 option): RF 50  $\Omega$ , USB, SENSOR, SD card on the front panel, all others on the rear panel.

Model with 3 HU (equipped with the R&S®SMAB-B93 option): all connectors on front panel.

Model with 2 or 3 HU and equipped with an R&S®SMAB-B80/-B81/-B82 rear panel connector option: all except USB on the rear panel.

RF 50 Ω	RF output		
	R&S®SMAB-B103/-B106	N female	
	R&S®SMAB-B112/-B120/-B131/	test port adapter, PC 2.92 mm female	
	-B140/-B140N	(interchangeable port connector system)	
	R&S®SMAB-B150/-B167/-B150N/	1.85 mm female	
	-B167N	(instrument equipped with	
		interchangeable 1.85 mm female/female	
		wear and tear adapter, factory calibration	
		plane is at the output of the adapter)	
LF	LF generator output	BNC female	
Ext 1, Ext 2	input for external analog modulation	BNC female	
	(AM, FM, φM, Scan AM)		
Input impedance		100 kΩ; 600 Ω or 50 Ω (nom.)	
Input sensitivity	AM, FM, φM: peak value for set deviation	1 V (nom.)	
Input voltage range	Scan AM		
	Ext 1	-6 V to 0 V	
	Ext 2	-1 V to 0 V	
Input damage voltage	50 Ω input impedance	< -7  V or  > +7  V	
	600 Ω and $100$ kΩ input impedance	< -10 V or > +10 V	
Pulse Ext	input for external pulse modulation,	BNC female/digital signal	
	external trigger input for pulse generator,		
	external gate input for pulse generator		
Input impedance	selectable	10 kΩ or 50 Ω (nom.)	
Input voltage	TTL, CMOS compatible		
	threshold voltage	0 V to 2.0 V (nom.)	
Input damage voltage		< -0.5  V or  > +5  V	
Input polarity	selectable	normal, inverse	
Pulse Video	pulse generator output,	BNC female/digital signal	
	video output for external pulse modulation		
Pulse Sync	synchronizing output for pulse generator	BNC female/digital signal	
Sensor	connector for R&S®NRP power sensor	6-pin ODU mini-snap series B,	
		mechanically compatible with 8-pin ODU	
		mini-snap series B	
USB	USB 2.0 connector for external USB	USB type A	
	devices such as mouse, keyboard,		
	R&S®NRP power sensors (with		
	R&S®NRP-Z4 adapter cable), memory		
	stick for software update and data		
	exchange or USB serial adapter for		
	RS-232 remote control		
SD	with R&S®SMAB-B85 option	SD card slot	
	for removable mass storage		
Clk Syn	clock synthesizer output SMA female		
Clk Syn_N	clock synthesizer inverted output	SMA female	

#### **Rear panel connectors**

D-(1-		DNO (
Ref In	external reference frequency input	BNC female
Input damage level		> 20 dBm
Ref Out	reference frequency output	BNC female
Ref In 1 GHz	external 1 GHz reference frequency input	SMA female
Input damage level		> 20 dBm
Ref Out 1 GHz	ultra low noise 1 GHz reference frequency output	SMA female
Ext Tune	input for electronic tuning of internal reference frequency	BNC female
Inst Trig	trigger input for sweep and list mode	BNC female/digital signal
Signal Valid	output for triggering external devices, high state indicates that the instrument has settled to its final value	BNC female/digital signal
V/GHz X-Axis	with R&S®SMAB-B28 option, delivers voltage level proportional to absolute sweep frequency or sweep progress	BNC female
Load impedance		≥ 1 kΩ
Z-Axis	with R&S®SMAB-B28 option, delivers pulses with different levels to indicate frequency markers and blanking signals	BNC female
Load impedance		≥ 10 kΩ
Stop	with R&S®SMAB-B28 option, bidirectional signal to indicate halted sweep or to stop sweep by external device	BNC female/digital signal
Input polarity		low active
Marker User 1	with R&S®SMAB-B28 option, pulse output to mark selected frequencies	BNC female/digital signal
Input polarity	selectable	normal, inverse
LAN	provides remote control functionality and other services, see section "Remote control"	RJ-45
USB	USB 2.0 connector for external USB devices such as mouse, keyboard, R&S®NRP power sensors (with adapter cable R&S®NRP-Z4), memory stick for software update and data exchange or USB serial adapter for RS-232 remote control	USB type A
USB In	with R&S®SMAB-B86 option, USB 2.0, remote control of instrument	USB type micro-B
IEEE-488	with R&S®SMAB-B86 option, remote control of instrument via GPIB	24-pin Amphenol series 57 female

## **General data**

Power rating		
Rated voltage		100 V to 240 V AC (± 10 %)
Rated frequency		50 Hz to 60 Hz (± 5 %), 400 Hz (± 5 %)
Rated current	model with 2 HU	3.5 A to 1.6 A (50 Hz to 60 Hz),
Nated Current	(R&S®SMAB-B92 option)	3.5 A to 2.9 A (400 Hz)
	model with 3 HU	7.3 A to 4.6 A (50 Hz to 60 Hz/400 Hz)
	(R&S®SMAB-B93 option)	7.071 (00 112 (0 00 1121 400 112)
Rated power	model with 2 HU	300 W (meas.)
rated power	(R&S®SMAB-B92 option),	ooo II (model)
	when fully equipped	
	model with 3 HU	380 W (meas.)
	(R&S®SMAB-B93 option),	300 W (meas.)
	when fully equipped	
Power factor correction	when fully equipped	in line with EN 61000-3-2
Product conformity		III IIIIC WILIT EIV 01000 3 Z
Electromagnetic compatibility	EU: in line with EMC Directive	applied harmonized standards:
	2014/30/EU	<ul> <li>EN 61326-1 (industrial environment)</li> </ul>
	2014/30/20	• EN 61326-2-1
		• EN 55011 class A
		• EN 61000-3-2
Clastrical actaty	Elle in line with Low Voltage Directive	EN 61000-3-3      applied bermanized standards
Electrical safety	EU: in line with Low Voltage Directive	applied harmonized standard: EN 61010-1
	2014/35/EU USA	
		UL 61010-1 CAN/CSA-C22.2 No. 61010-1
nto-motional actative annual acta	Canada  VDE – Association for Electrical,	
International safety approvals	*	GS mark 40045930
	Electronic and Information Technologies  CSA – Canadian Standards Association	CCA morts 70100101
Mechanical resistance	CSA – Canadian Standards Association	CSA <sub>UL</sub> mark 70108101
Vibration	sinusoidal	5 Hz to 55 Hz, 0.15 mm amplitude const
Vibration	omacoidai	55 Hz to 150 Hz, 0.5 g const.,
		in line with EN 60068-2-6
	random	10 Hz to 300 Hz,
	random	1.2 g (RMS) acceleration,
		in line with EN 60068-2-64
Shock		40 g shock spectrum, in line with
SHOCK		MIL-STD-810E, method 516.4,
Environmental conditions		procedure I
	operating	0 °C to +55 °C
Temperature range	operating operating, with R&S®SMAB-B36S option	0 °C to +45 °C
		-40 °C to +71 °C,
	storage	temperature gradient < 5 K/h
Damp heat		+40 °C, 90 % rel. humidity, steady state,
Damp neat		in line with EN 60068-2-78
Altitudo	operating,	
Altitude	1 3,	4600 m (15000 ft)
	linear derating of max. ambient	
	temperature to +45 °C starting at	
	altitude = 3000 m	4000 (45000 ft)
	transport	4600 m (15000 ft)

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Weight and dimensions		
Dimensions (W × H × D)	model with 2 HU	460 mm × 107 mm × 503 mm
	(R&S®SMAB-B92 option)	$(18.1 \text{ in} \times 4.21 \text{ in} \times 19.8 \text{ in})$
	without front handles and feet	445 mm × 89 mm × 485 mm
		$(17.5 \text{ in} \times 3.5 \text{ in} \times 19.1 \text{ in})$
	model with 3 HU	460 mm × 151 mm × 503 mm
	(R&S®SMAB-B93 option)	(18.1 in × 5.95 in × 19.8 in)
	without front handles and feet	445 mm × 133 mm × 485 mm
		(17.5 in × 5.24 in × 19.1 in)
Weight	model with 2 HU	14.4 kg (31.7 lb)
	(R&S®SMAB-B92 option),	
	when fully equipped	
	model with 3 HU	18.0 kg (39.6 lb)
	(R&S®SMAB-B93 option),	
	when fully equipped	
Display		
Resolution		800 x 480 pixel
Size	2 HU model	5" touch display
	3 HU model	7" touch display
Calibration interval		
Recommended calibration interval	operation 40 h/week in the full range of	3 years
	the specified environmental conditions	

# **Ordering information**

R&S®SMAB-Bxxx = hardware option R&S®SMAB-Kxxx = software/keycode option

Designation	Туре	Order No.
Signal generator <sup>13</sup>	R&S®SMA100B	1419.8888.02
including power cable and quick start guide		
Options	·	
Frequency options		
8 kHz to 3 GHz	R&S®SMAB-B103	1420.8488.02
8 kHz to 6 GHz	R&S®SMAB-B106	1420.8588.02
8 kHz to 12.75 GHz	R&S®SMAB-B112	1420.8688.02
8 kHz to 20 GHz	R&S®SMAB-B120	1420.8788.02
8 kHz to 31.8 GHz	R&S®SMAB-B131	1420.8888.02
8 kHz to 40 GHz	R&S®SMAB-B140	1420.8988.02
8 kHz to 40 GHz	R&S®SMAB-B140N	1420.8965.02
8 kHz to 50 GHz	R&S®SMAB-B150	1420.9049.02
8 kHz to 50 GHz	R&S®SMAB-B150N	1420.9026.02
8 kHz to 67 GHz	R&S®SMAB-B167	1420.9149.02
8 kHz to 67 GHz	R&S®SMAB-B167N	1420.9126.02
Platform height options		
2 HU with 5" touch display	R&S®SMAB-B92	1420.8288.04
3 HU with 7" touch display	R&S®SMAB-B93	1420.8388.04
Phase noise performance and reference oscillator options	·	·
High performance OCXO reference oscillator 14	R&S®SMAB-B1H	1420.8188.02
Low phase noise <sup>14</sup>	R&S®SMAB-B709	1420.9849.02
Improved close-in phase noise performance for R&S®SMAB-B106/-B112/-B120/-B131/-B140/-B150/-B167 14	R&S®SMAB-B710	1420.8007.02
Improved close-in phase noise performance for R&S®SMAB-B103 14	R&S®SMAB-B710N	1420.8107.02
Ultra low phase noise for R&S®SMAB-B106/-B112/-B120/-B131/-B140/-B150/-B167 <sup>14</sup>	R&S®SMAB-B711	1420.8020.02
Ultra low phase noise for R&S®SMAB-B103 14	R&S®SMAB-B711N	1420.8120.02
100 MHz, 1 GHz ultra low noise reference input/output	R&S®SMAB-K703	1420.9761.02
Flexible reference input from 1 MHz to 100 MHz	R&S®SMAB-K704	1420.9778.02
Output power options		
High output power 3 GHz/6 GHz	R&S®SMAB-K31	1420.7100.02
Ultra high output power 3 GHz/6 GHz 15	R&S®SMAB-B32	1420.7200.02
High output power 12.75 GHz/20 GHz	R&S®SMAB-K33	1420.7300.02
Ultra high output power 12.75 GHz/20 GHz 16	R&S®SMAB-B34	1420.7400.02
High output power 31.8 GHz/40 GHz <sup>17</sup>	R&S®SMAB-B35	1420.7500.02
Ultra high output power 31.8 GHz/40 GHz 18	R&S®SMAB-K36	1420.9178.02
Super ultra high output power 31.8 GHz/40 GHz <sup>19</sup>	R&S®SMAB-B36S	1420.9190.02
High output power 50 GHz <sup>17</sup>	R&S®SMAB-B37	1420.7700.02
Ultra high output power 50 GHz 20	R&S®SMAB-K38	1420.9255.02
High output power 67 GHz <sup>17</sup>	R&S®SMAB-B39	1420.7900.02
Ultra high output power 67 GHz <sup>21</sup>	R&S®SMAB-K40	1420.9278.02

<sup>13</sup> The base unit can only be ordered with an R&S®SMAB-B1xx frequency option and an R&S®SMAB-B92 or R&S®SMAB-B93 platform height option.

<sup>14</sup> Only one of the following six options can be installed: R&S®SMAB-B1H, R&S®SMAB-B709, R&S®SMAB-B710, R&S®SMAB-B710N, R&S®SMAB-B711N.

 $<sup>^{\</sup>rm 15}$  R&S@SMAB-B32 can only be ordered in combination with R&S@SMAB-K31.

<sup>&</sup>lt;sup>16</sup> R&S®SMAB-B34 can only be ordered in combination with R&S®SMAB-K33.

 $<sup>^{\</sup>rm 17}$  Requires R&S $^{\rm 8}$ SMAB-B93 3 HU option.

<sup>&</sup>lt;sup>18</sup> R&S®SMAB-K36 can only be ordered in combination with R&S®SMAB-B35.

 $<sup>^{\</sup>rm 19}$  R&S@SMAB-B36S can only be ordered in combination with R&S@SMAB-B35 and R&S@SMAB-K36.

 $<sup>^{20}\,</sup>$  R&S®SMAB-K38 can only be ordered in combination with R&S®SMAB-B37.

<sup>&</sup>lt;sup>21</sup> R&S<sup>®</sup>SMAB-K40 can only be ordered in combination with R&S<sup>®</sup>SMAB-B39.

Designation	Туре	Order No.
Analog modulation options		
High performance pulse modulator	R&S®SMAB-K22	1420.9710.02
Pulse generator	R&S®SMAB-K23	1420.9726.02
Multifunction generator	R&S®SMAB-K24	1420.9732.02
VOR/ILS	R&S®SMAB-K25	1420.9855.02
Pulse train <sup>22</sup>	R&S®SMAB-K27	1420.9749.02
AM/FM/φM	R&S®SMAB-K720	1420.9790.02
Scan AM <sup>23</sup>	R&S®SMAB-K721	1420.9784.02
Chirp signal generation <sup>24</sup>	R&S®SMAB-K725	1420.9861.02
Additional performance options		
Power analysis	R&S®SMAB-K28	1420.9755.02
Ramp sweep	R&S®SMAB-B28	1420.6579.02
Differential clock synthesizer 3 GHz	R&S®SMAB-B29	1420.8088.02
Clock synthesizer frequency extension to 6 GHz (not available for instruments equipped with R&S®SMAB-B103)	R&S®SMAB-K722	1420.9810.02
High dynamic uninterrupted level sweep <sup>25</sup>	R&S®SMAB-K724	1420.9832.02
Other options		-
Rear panel connectors (3 GHz/6 GHz)	R&S®SMAB-B80	1420.6504.02
Rear panel connectors (12.75 GHz/20 GHz/31.8 GHz/40 GHz), PC 2.92 mm	R&S®SMAB-B81	1420.6510.02
Rear panel connectors (50 GHz/67 GHz), PC 1.85 mm	R&S®SMAB-B82	1420.6527.02
Removable mass storage	R&S®SMAB-B85	1420.6556.02
Remote control GPIB and USB	R&S®SMAB-B86	1420.6562.02
Spare SD card	R&S <sup>®</sup> SMAB-Z10	1420.6662.02
Recommended extras		
19" rack adapter for 2 HU model	R&S®ZZA-KNP21	1177.8803.00
19" rack adapter for 3 HU model	R&S®ZZA-KNP31	1177.8810.00
Transport case for 2 HU and 3 HU model	R&S®ZZK-CASE	1174.1443.02
USB serial adapter, for RS-232 remote control	R&S®TS-USB1	6124.2531.00
Adapters for instruments with an R&S®SMAB-B112/-B120/-B131/-B140	(N) frequency option	
Test port adapter, 2.4 mm female		1088.1627.02
Test port adapter, 2.92 mm female		1036.4790.00
Test port adapter, 2.92 mm male		1036.4802.00
Test port adapter, N female		1036.4777.00
Test port adapter, N male		1036.4783.00
Adapter for instruments with an R&S®SMAB-B150(N)/-B167(N) frequer	ncy option	
Wear and tear adapter, 1.85 mm female/female		3588.9654.00
Documentation		
Documentation of calibration values	R&S®DCV-2	0240.2193.18
R&S®SMA100B accredited calibration; up to 6 GHz	R&S®ACASMA100B	3598.3307.03
R&S®SMA100B accredited calibration; 12.75 GHz to 40 GHz	R&S®ACASMA100B	3598.3236.03
R&S®SMA100B accredited calibration; 50 GHz to 67 GHz	R&S®ACASMA100B	3598.3207.03

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<sup>&</sup>lt;sup>22</sup> Requires R&S®SMAB-K23 pulse generator option.

<sup>&</sup>lt;sup>23</sup> Requires R&S®SMAB-K720 AM/FM/φM option. For instruments with a serial number < 102000, contact the Rohde & Schwarz service department.

<sup>&</sup>lt;sup>24</sup> Requires R&S®SMAB-K22 high performance pulse modulator option, R&S®SMAB-K23 pulse generator option and R&S®SMAB-K720 AM/FM/φM option. FW version > 4.70.xxx required.

 $<sup>^{25}</sup>$  For instruments with a serial number < 102000, contact the Rohde & Schwarz service department.

## Warranty and service

Warranty			
Base unit		1 year	
All other items		1 year	
Service options			
•	Service plans	On demand	
Calibration	up to five years 26	pay per calibration	
Warranty and repair	up to five years <sup>26</sup>	standard price repair	
Find out more about our servi www.rohde-schwarz.com/service	ce portfolio under: e-support/service/overview/service-overview	<u>v 229461.html</u>	

<sup>&</sup>lt;sup>26</sup> For extended periods, contact your Rohde & Schwarz sales office.

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- ▶ Local and personalized
- Customized and flexibleUncompromising qualityLong-term dependability

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